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Title: "Giant" nanocrystal quantum dots for light-emission applications

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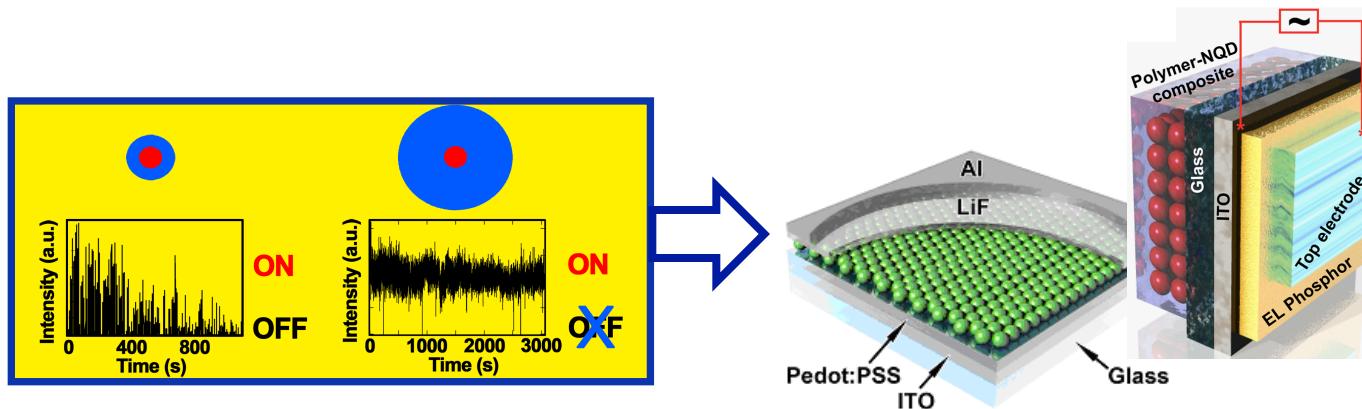
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“Giant” Nanocrystal Quantum Dots for Light-Emission Applications

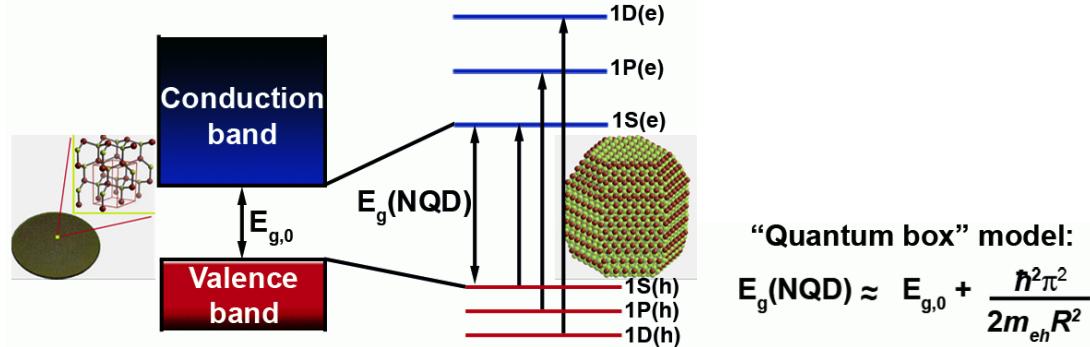
Jennifer Hollingsworth

*Los Alamos National Laboratory
Center for Integrated Nanotechnologies:
Nanoscale Science Research Center and User Facility*

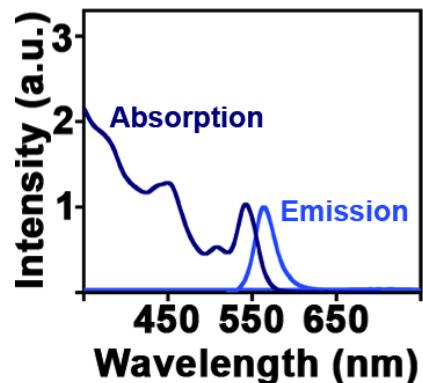


Quantum Dots (QDs): Functionality for Light-Emission Applications

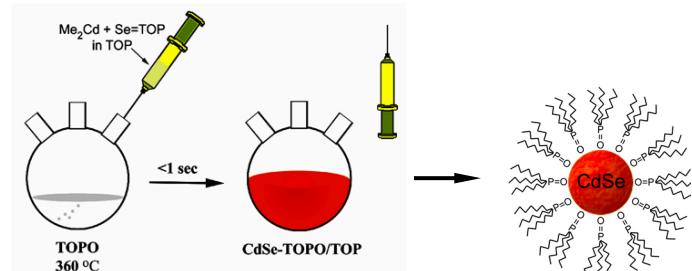
- Quantum-confinement effects afford functionality



- Size-tunable bandgap / fluorescence
- Narrow & bright emission
- Broadband & efficient absorption



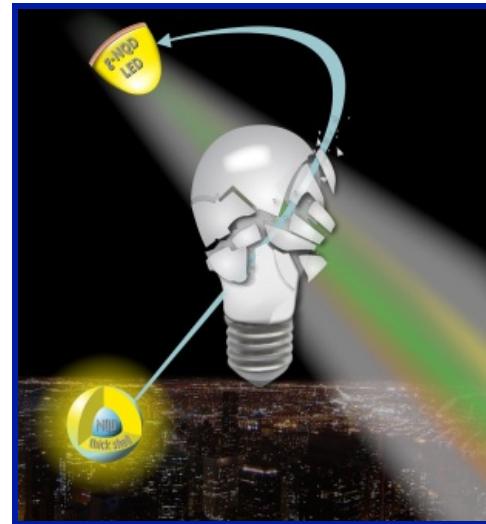
- Low-cost / scalable synthesis
- Solution processible
- High-quality: Low polydispersity (+/- 4%) & single-crystalline



Quantum Dots: Functionality for Light-Emission Applications

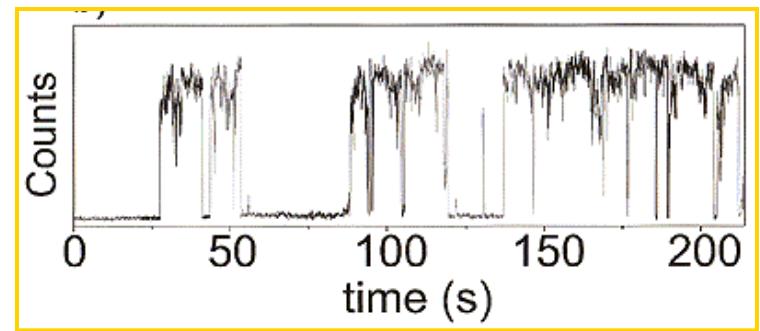
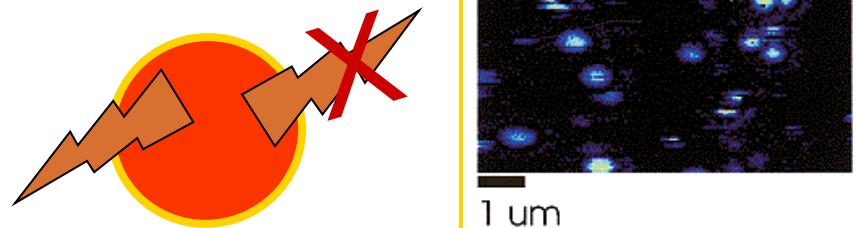
- Potential applications

- ✓ Biological optical tags / reporters
- ✓ Color-tunable lasing
- ✓ Single-photon source
- ✓ Light-emitting diodes (solid-state lighting)



The darker side of QDs: Blinking and non-radiative Auger recombination

- Quantum dot fluorescence intermittency

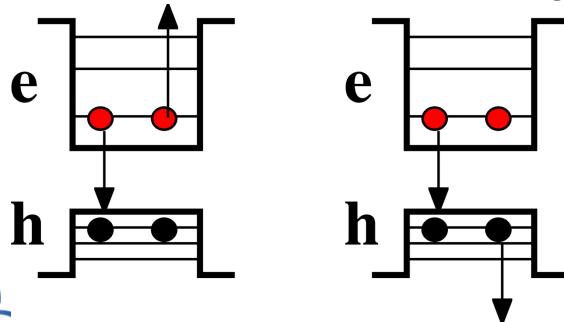


▪ Nirmal et al. *Nature* (1996) 802
▪ Efros *Nature Mater.* (2008) 612

- Conventional blinking model:

- QDs randomly cycle through uncharged and charged states
- In charged state, QD blinks 'off' due to Auger recombination

- Efficient non-radiative Auger recombination

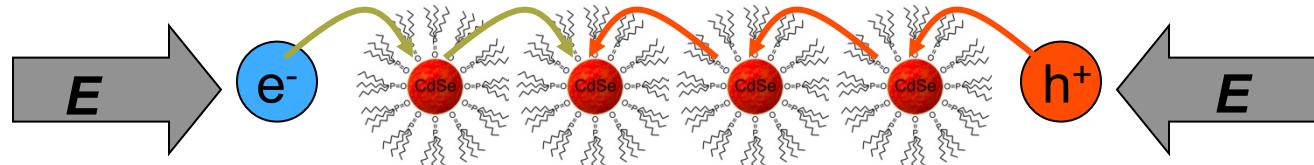


- Reduces optical gain lifetimes
- Reduces optical gain bandwidth
- Restricts time available to extract multiple excitons
- Limits ability to reliably extract single photons
- *Leads to non-radiative losses in LEDs (via charge build-up)*

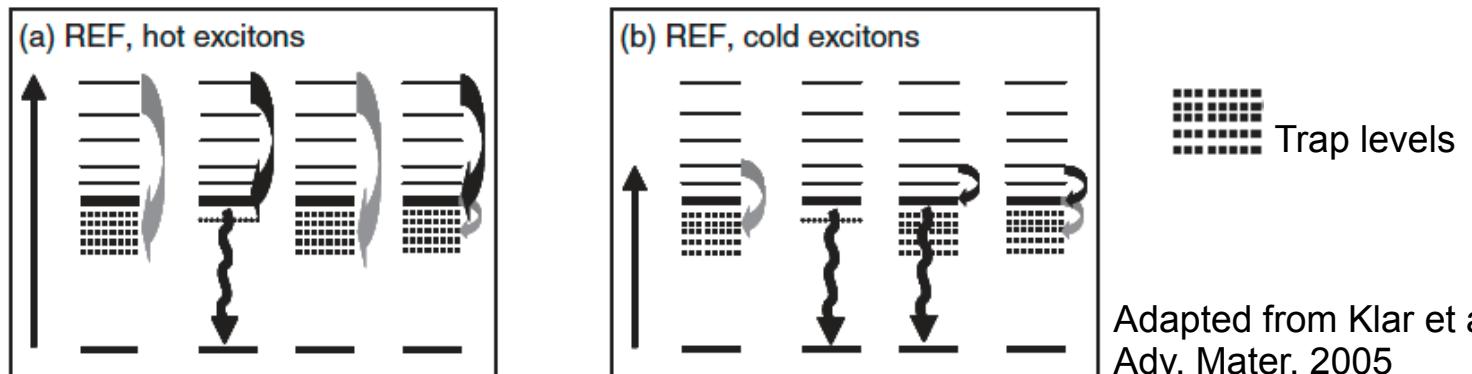
The darker side of QDs: Traits that impede solid-state performance

Why are solid-state QD quantum yields an order-of-magnitude less than solution QD quantum yields?

- Optical properties depend on organic ligand layer
 - Damage to ligands diminishes NQD performance
 - Ligands can impede charge transport / injection



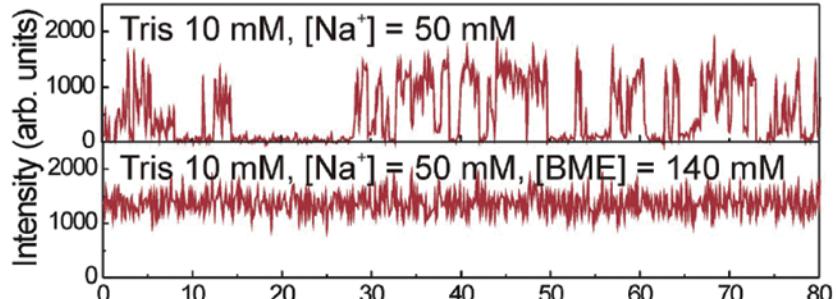
- Efficient QD-QD energy transfer in close-packed films
 - Excitons “funnel” to lowest-energy state, which can be a non-emitting trap state



QD blinking: The subject of intense investigation

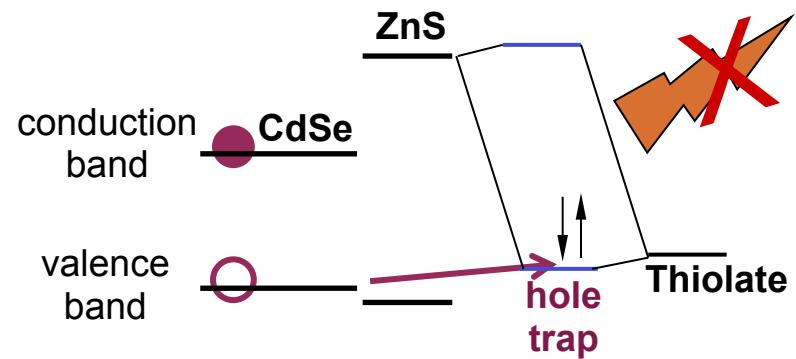
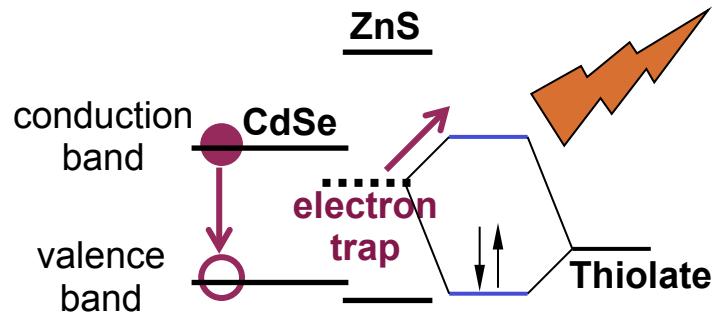
- Early attempts to suppress blinking used charge-mediators/compensators to suppress charging

- Short-chain thiols: “BME”
- Organic conjugated ligands
- Propyl gallate (“antioxidant”)
- Hohng & Ha *JACS* 2004, 126, 1324; Hammer et al. *JPC B* 2006, 110, 14167; Fomenko & Nesbitt *Nano Lett.* 2008, 8, 287



- “Ligand” approach hard to reproduce and not robust

- Effects are concentration, time, pH dependent
- Thiolate ion passivates electron traps at low concentrations (acidic pH)
- Thiolate introduces hole traps at high concentrations (basic pH)



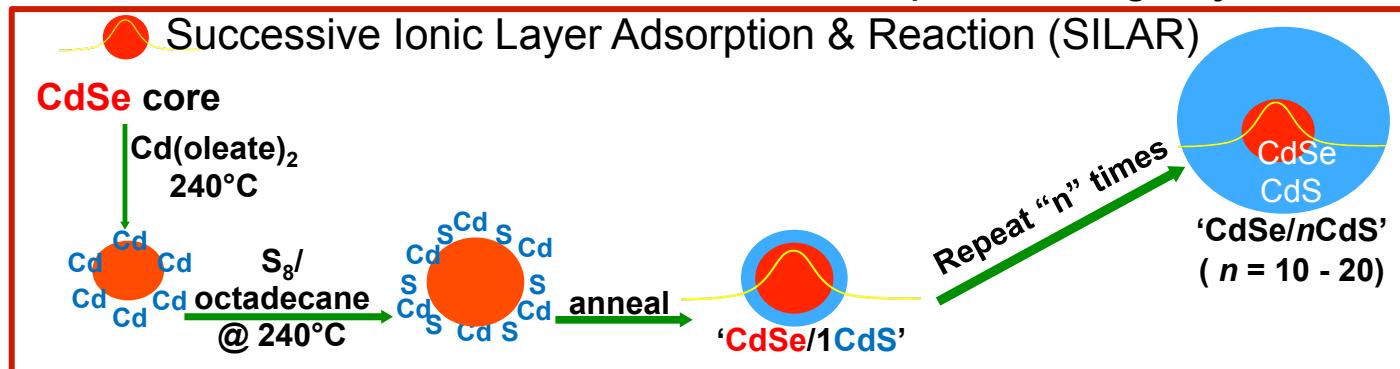
Conclusions from early work on QD blinking: Role of surface chemistry

- Careful application of charge-donating ligands affords “window of opportunity” for photoluminescence enhancement
- However, control and long-term stability difficult to achieve
- Clearly, charging and/or surface trap states play a key role

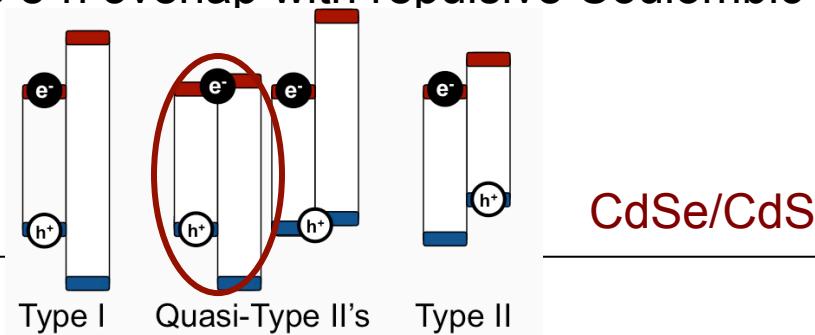
What about an inorganic approach?

Inorganic shell approach: *Is it possible to impact both charging/trapping and Auger recombination processes?*

- Epitaxial growth of wide-bandgap shell on a QD core improves PL efficiencies and stability
 - But, core/shell QDs still blink and still exhibit efficient Auger recombination
- Advanced 'shell engineering'
 - Thick shell to isolate carriers from surface / impede charge ejection

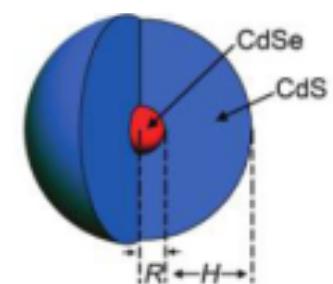
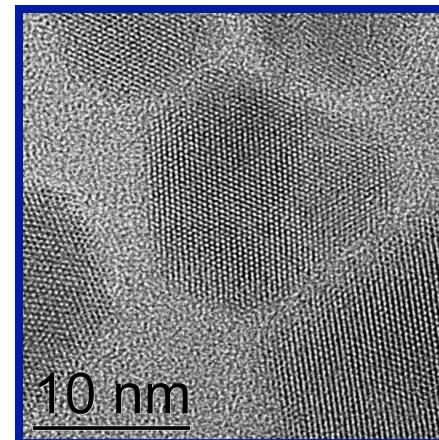
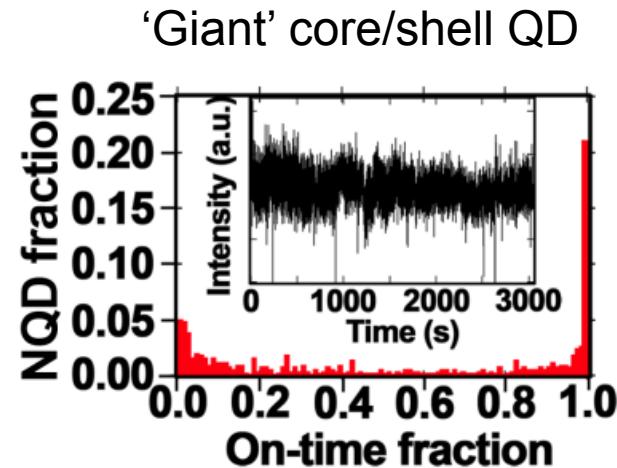
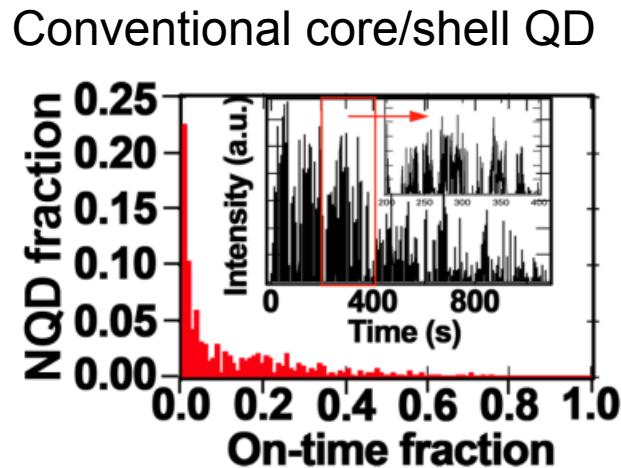


- 'Type-II' core/shell band alignments: Partial or full electron-hole spatial separation reduces e-h overlap with repulsive Coulombic interactions possible



‘Giant’ quantum dots: New functional class of QD

Single-dot-level optical stability: Suppressed blinking and photobleaching

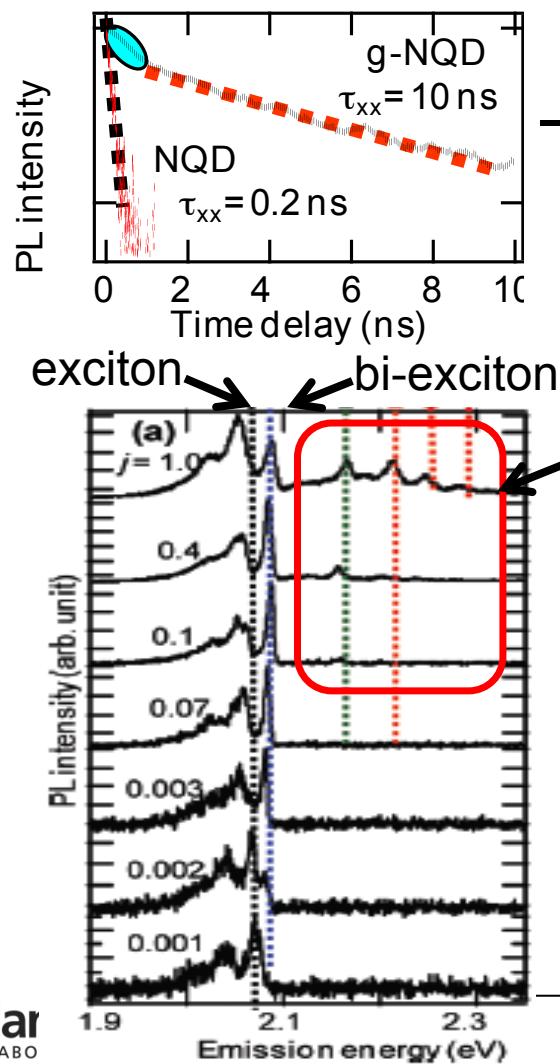


“Giant”: >10 monolayers of shell

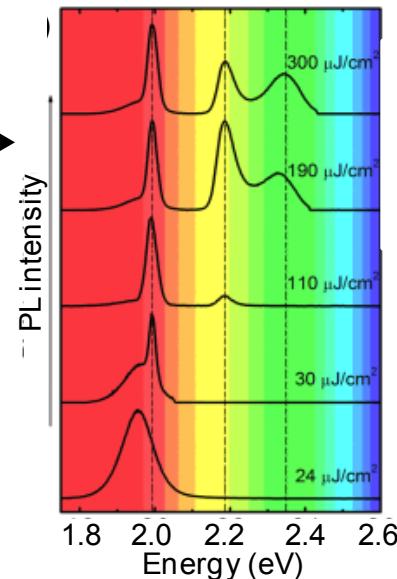
Blinking suppression:
Chen *et al.* *J. Am. Chem. Soc.* 2008
Vela *et al.* *J. Biophotonics* 2010
Hollingsworth *et al.* U.S. Patent 2011

‘Giant’ quantum dots: New functional class of QD

Evidence for suppressed Auger recombination



I.
Long-lived biexcitons

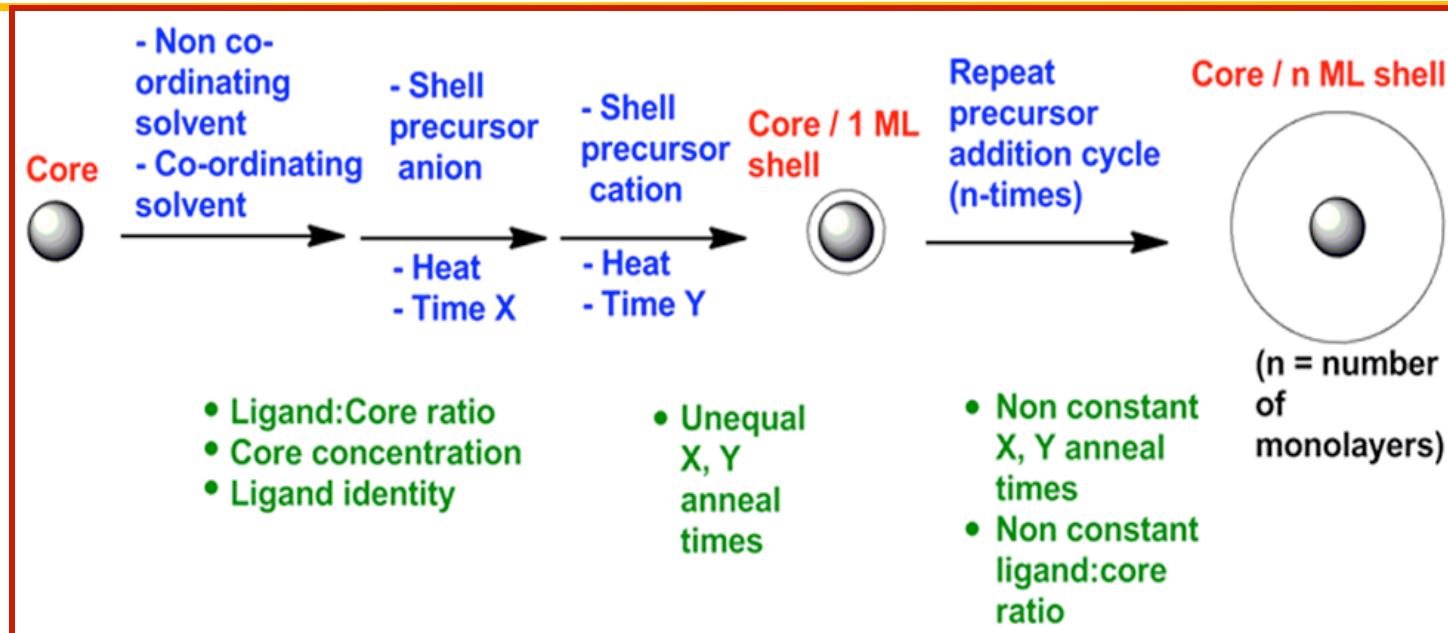


Optical amplification over a large bandwidth

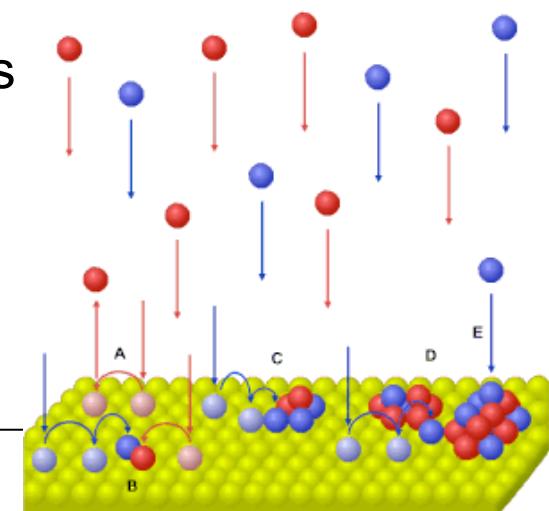
II.
Efficient biexciton and multiexciton emission

Auger recombination:
García-Santamaría *et al.* *Nano Lett.* 2009
Htoon *et al.* *Nano Lett.* 2010
Park *et al.* *Phys. Rev. Lett.* 2011

Process of thick-shell growth is complex: Numerous reaction parameters acting individually or in concert

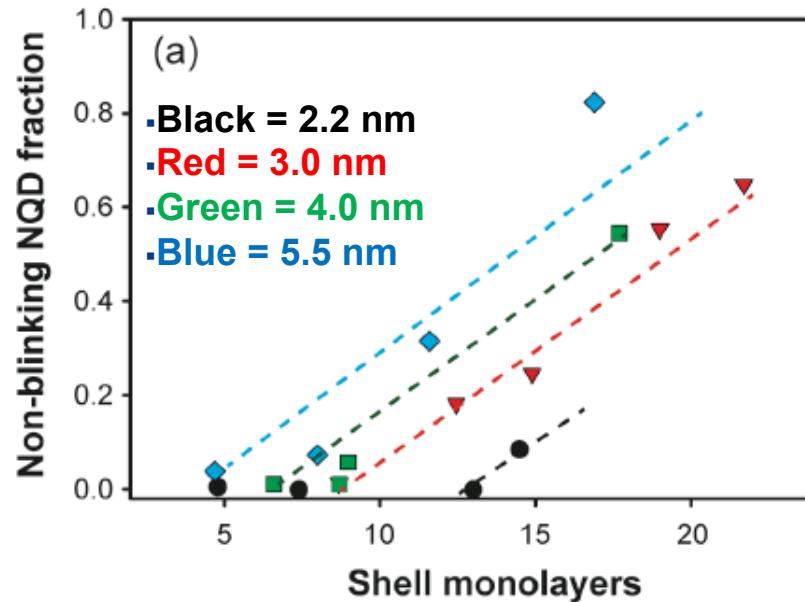


- Correlate process conditions that control adatom addition at the solution-NQD interface with properties
 - Particle shape
 - Crystal structure
 - Photophysical properties/performance (QYs, blinking, lifetimes)



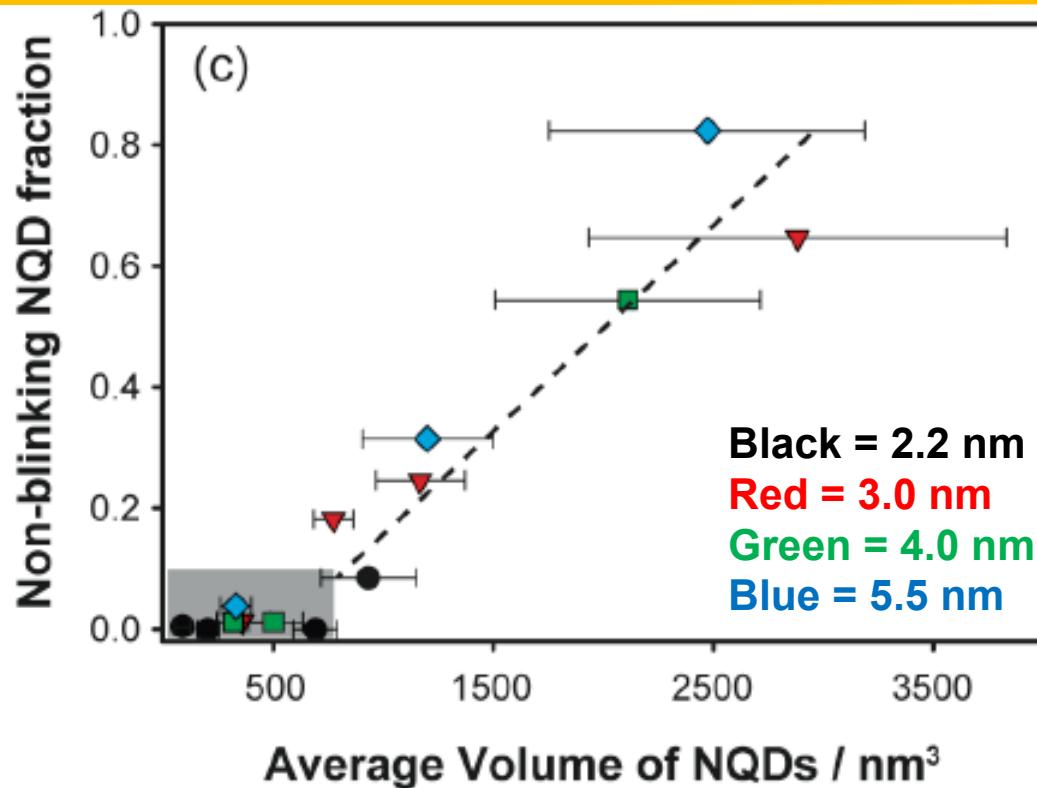
Beyond shell thickness: Effect of core size

- Non-blinking fraction as a function of core size (2.2 to 5.5 nm) and shell thickness



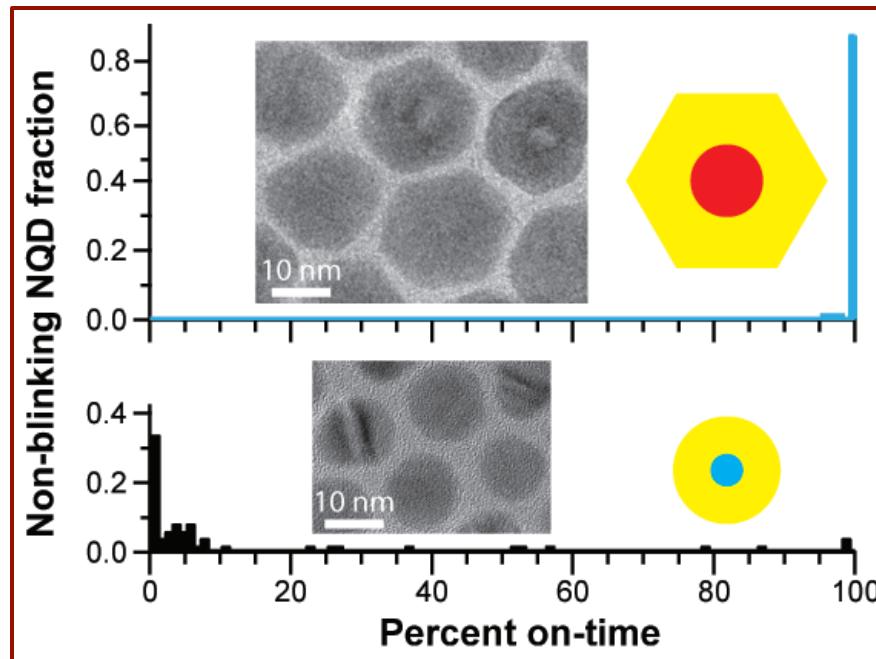
- Universal behavior: Non-blinking fraction increases as a function of shell thickness
- Onset of blinking-suppression begins at different shell thicknesses for different core sizes
 - Largest cores exhibit earliest onset of non-blinking
 - Smallest cores reach transition at much thicker shells

Understanding non-blinking behavior as a volume effect



- Non-blinking fraction trends explicitly with NQD volume
- “Volume threshold” at $\sim 750 \text{ nm}^3$
 - By either a combination of a small core and thick shell or a large core and thinner shell

Implications of core-size effect on blinking suppression

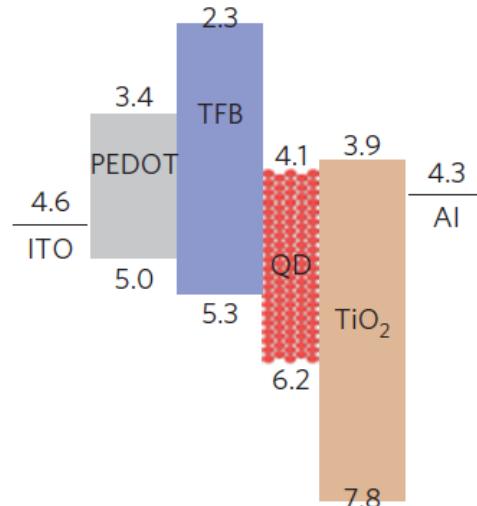
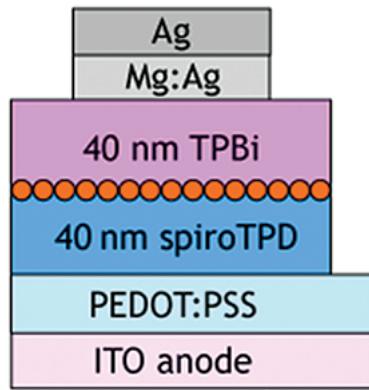


- Largest cores achieve fully suppressed blinking at thick shells (>85% of the NQDs are non-blinking)
- Smallest cores exhibit relatively little non-blinking behavior even after addition of ultra-thick CdS shells

Applications: QD LEDs

Conventional-QD light-emitting devices

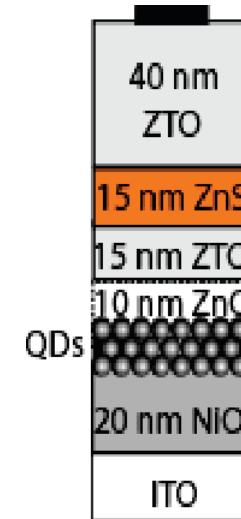
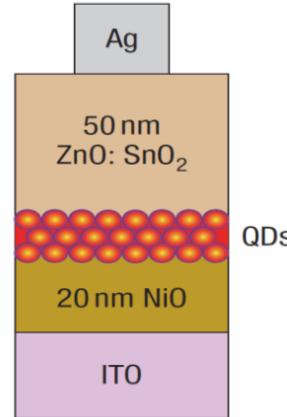
- Hybrid organic/inorganic devices



- EQE's up to ~3%
- Power efficiencies up to ~5 lmW⁻¹
- Now 18%!

- Kim et al. *Nat. Photonics* (2011) 176

- “All” inorganic devices



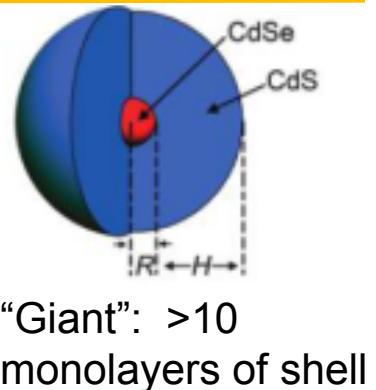
- EQE's up to 0.09% (left) and 0.2% (right)
- Now >1%

- Caruge et al. *Nat. photonics* (2008) 247
- Wood et al. *ACS Nano* (2009) 3581

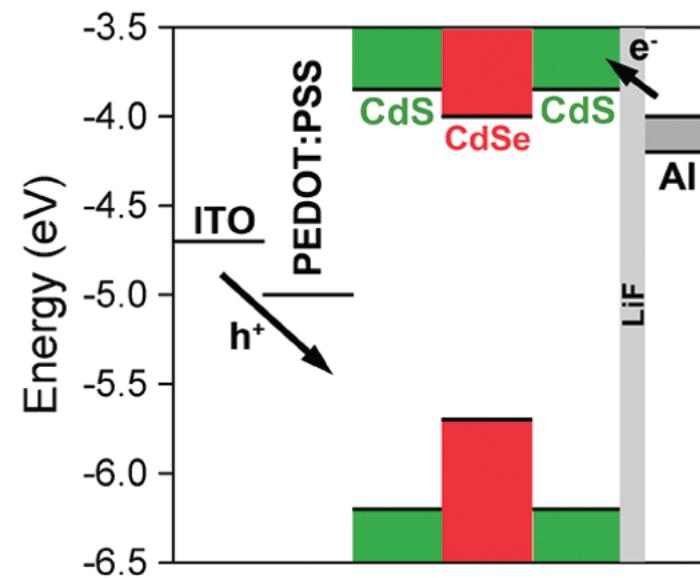
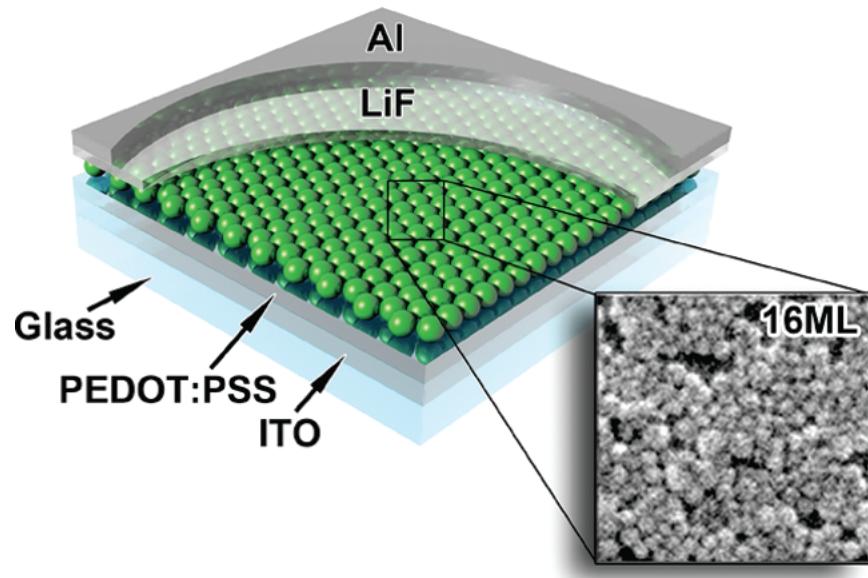
Applications: g-QD LEDs

Possible challenges to g-QD LEDs

- g-QD quantum yields ~50-60%
- Large per-particle volume translates to low density of emitter centers
- The thick shell might impede charge injection



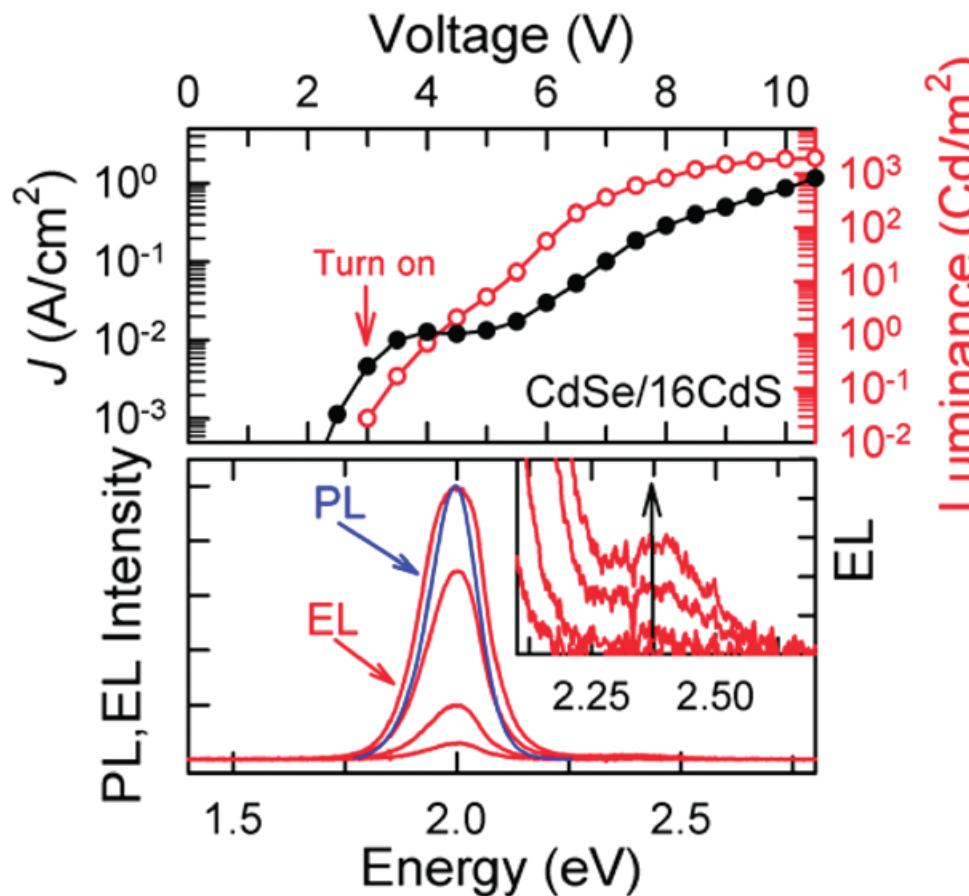
Test-bed direct-charge-injection light-emitting diode



Band alignments vs. electrode work functions

g-QD device outperforms similar QD device by two orders-of-magnitude!

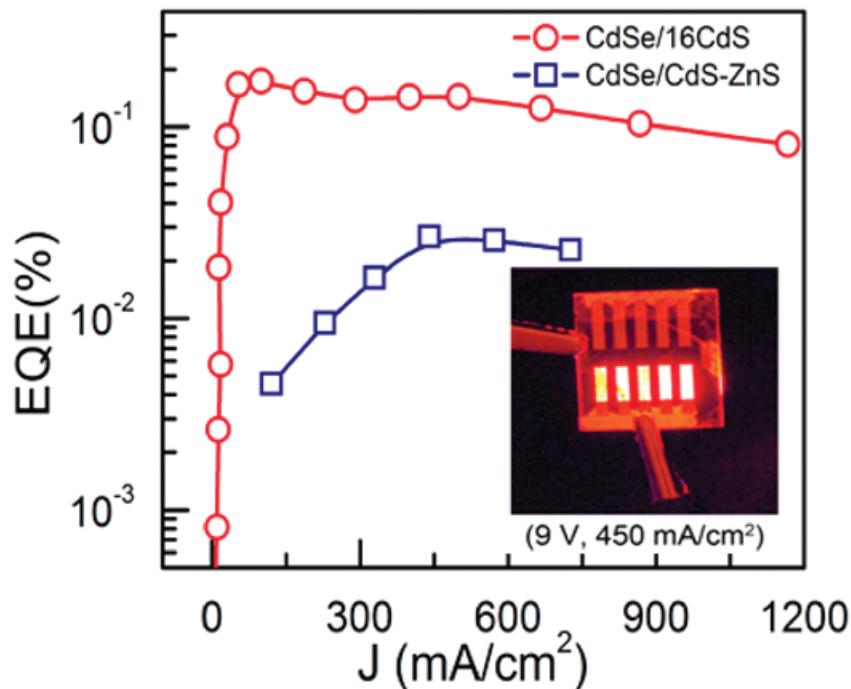
- Performance comparable to more sophisticated “all-inorganic” QD LEDs



- Low EL turn-on voltage: 3.0 V
- ‘Standard video brightness’ (200 Cd/m^2) reached at 6.5 V and 180 mA/cm^2
- High maximum luminance $\sim 2000 \text{ cd/m}^2$
- No deep-level trap emission even at high current densities
- Higher order excited states may be present due to Auger suppression!

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- Performance comparable to more sophisticated “all-inorganic” QD LEDs

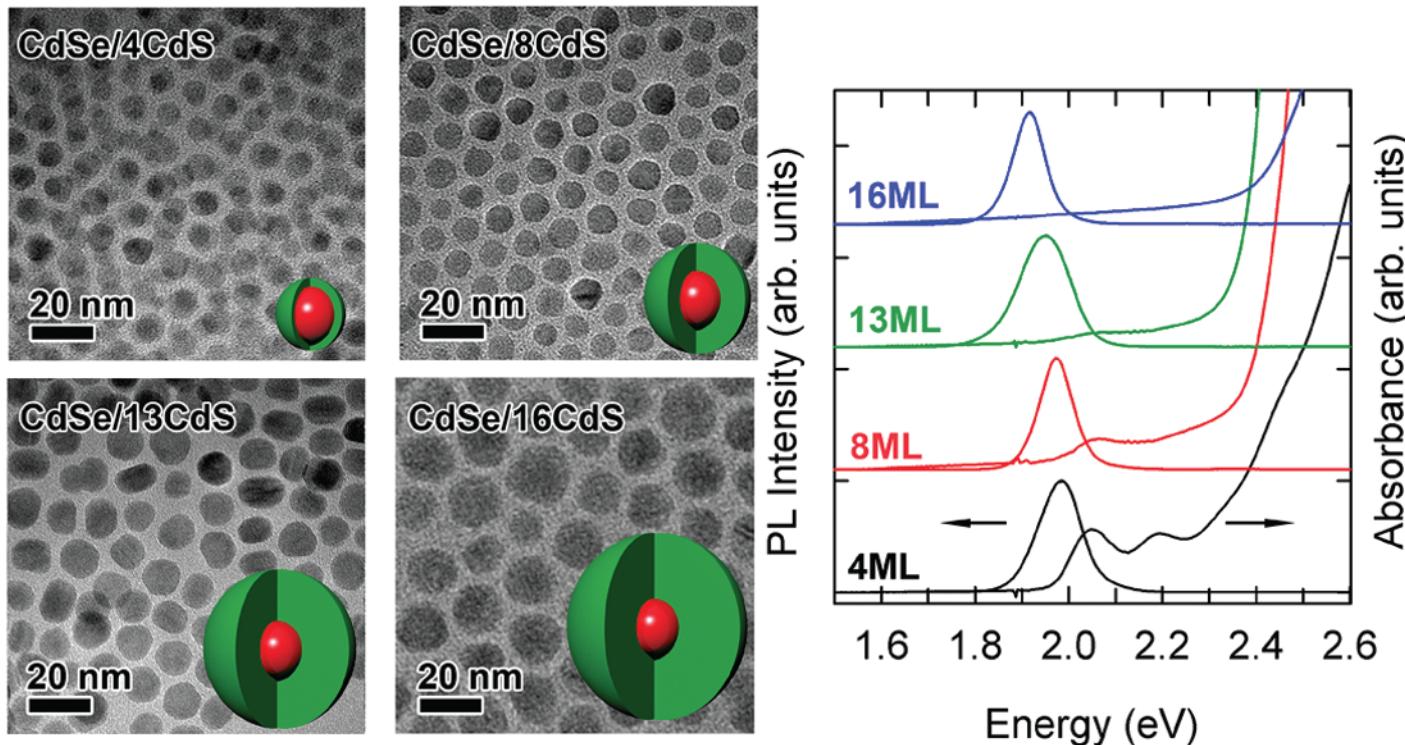


- Low EL turn-on voltage: 3.0 V
- ‘Standard video brightness’ (200 Cd/m²) reached at 6.5 V and 180 mA/cm²
- High maximum luminance ~2000 cd/m²
- No deep-level trap emission even at high current densities
- Higher order excited states may be present due to Auger suppression!
- Max. EQE of 0.17% reached at 100 mA/cm² (7.0 V) – NOT intrinsic limit
- Stable in repeated testing for >1 month stored/tested in air

Pal *et al.* *Nano Lett.* 2012, 12, 331-336

Directly probing the influence of shell thickness

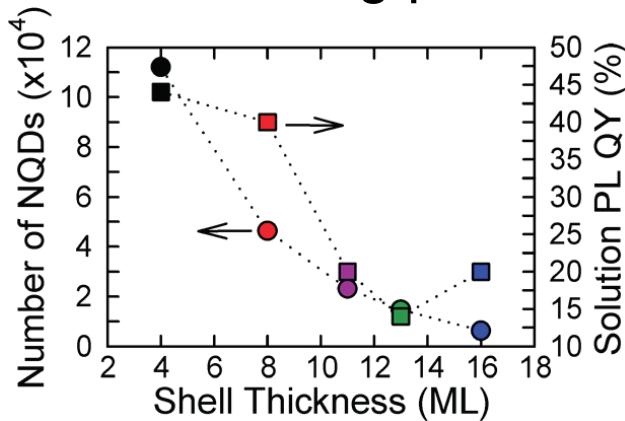
- Shell series (4CdS, 8CdS, 13CdS, 16CdS) compared



Pal *et al.* *Nano Lett.* 2012, 12, 331-336

QD LED performance as a function of shell thickness

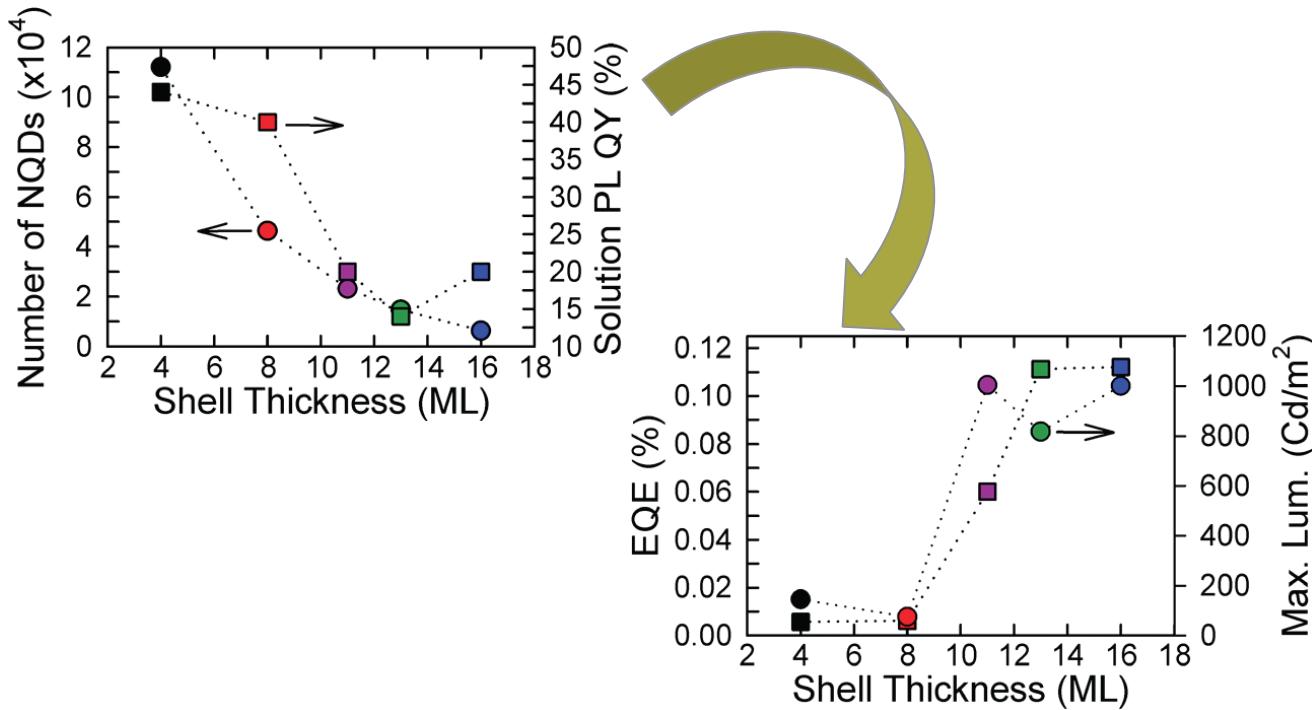
- The starting point



- g-QD solution-phase performance is poor compared to thinner-shell QDs
- Fewer g-QDs in a QD monolayer

QD LED performance as a function of shell thickness

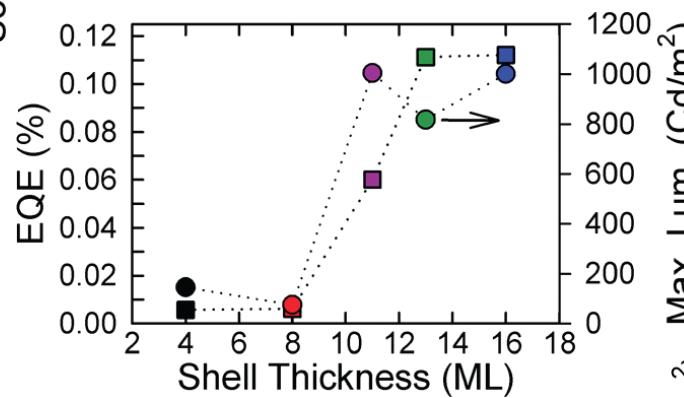
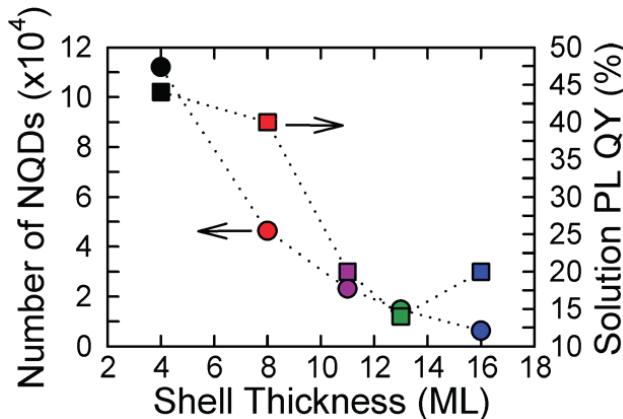
- g-QD solid-state performance surpasses solution-phase behavior



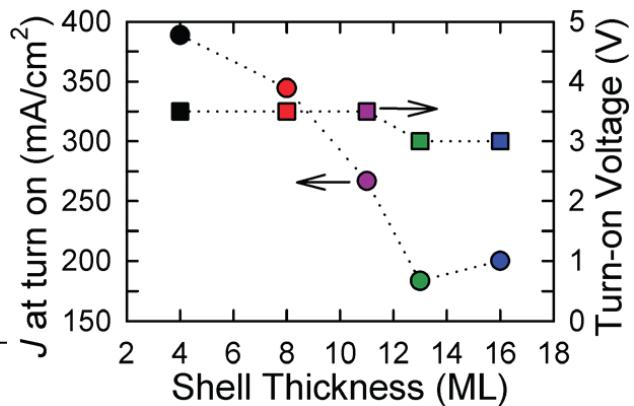
- EQE jumps for thick shells >10ML
- Shell thickness threshold for max. luminance, too

QD LED performance as a function of shell thickness

- g-QD solid-state performance surpasses solution-phase behavior

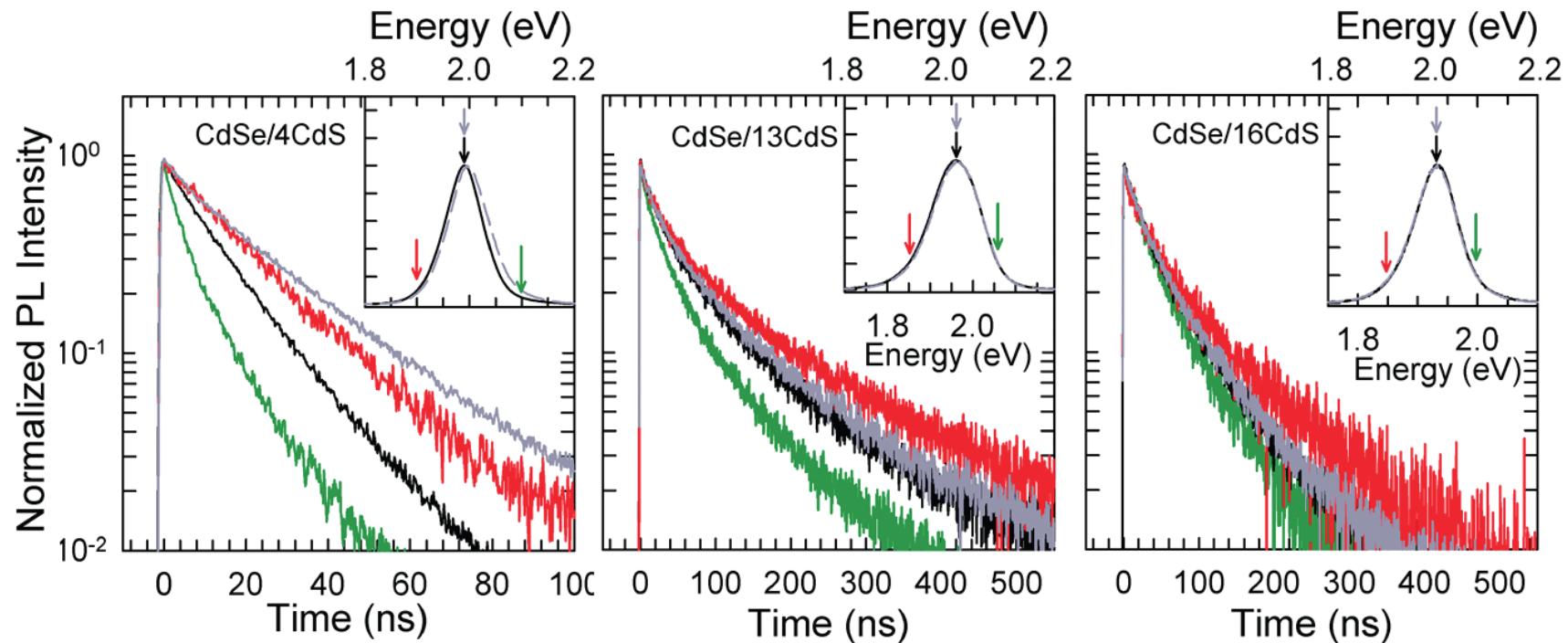


- Turn-on voltage: shell-thickness *independent*
- Reduced leakage current



Why do g-QDs outperform QDs in LEDs?

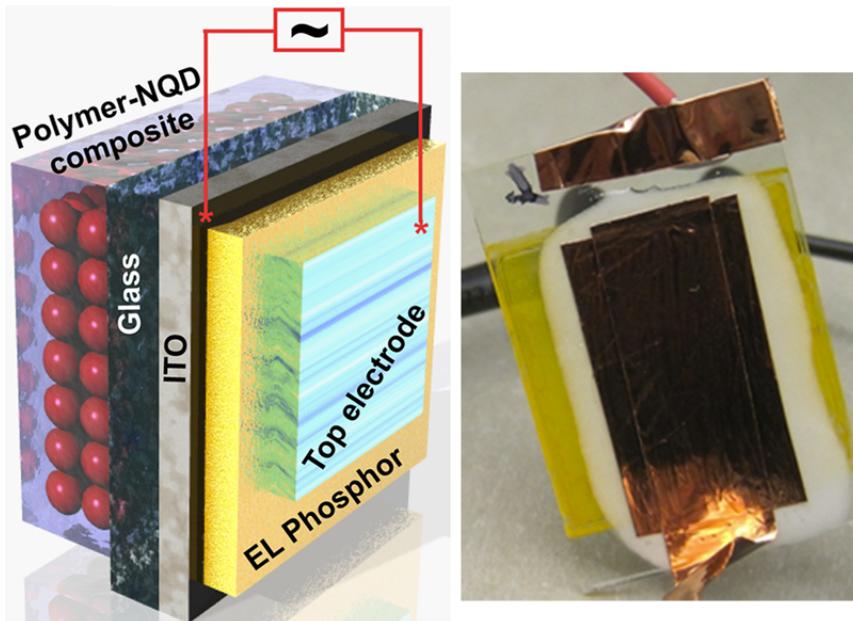
- g-QD luminescence is ligand-independent
- Auger recombination is suppressed; *charged excitons emit!*
- QD-QD energy transfer ‘shut-down’ at thick shells



- Photoluminescence decay curves

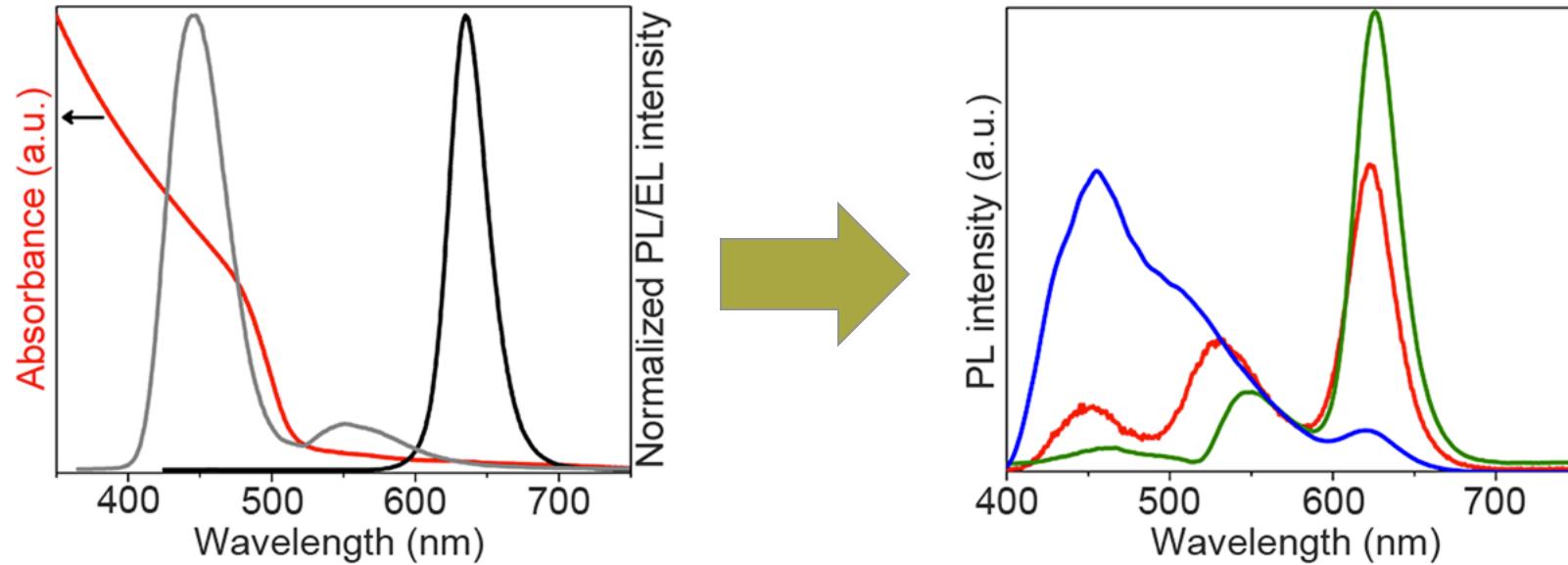
g-QDs as 'replacement' color-converting phosphors

- 'Test-bed' device architecture: so simple even a chemist can make it!
 - Commercial 'blue-emitting' electroluminescent (EL) phosphor: Cu/Cl-doped ZnS
 - EL phosphor sandwiched between indium tin oxide (ITO) bottom electrode and Cu tape top electrode
 - QD-polymer composite coated on backside of glass substrate



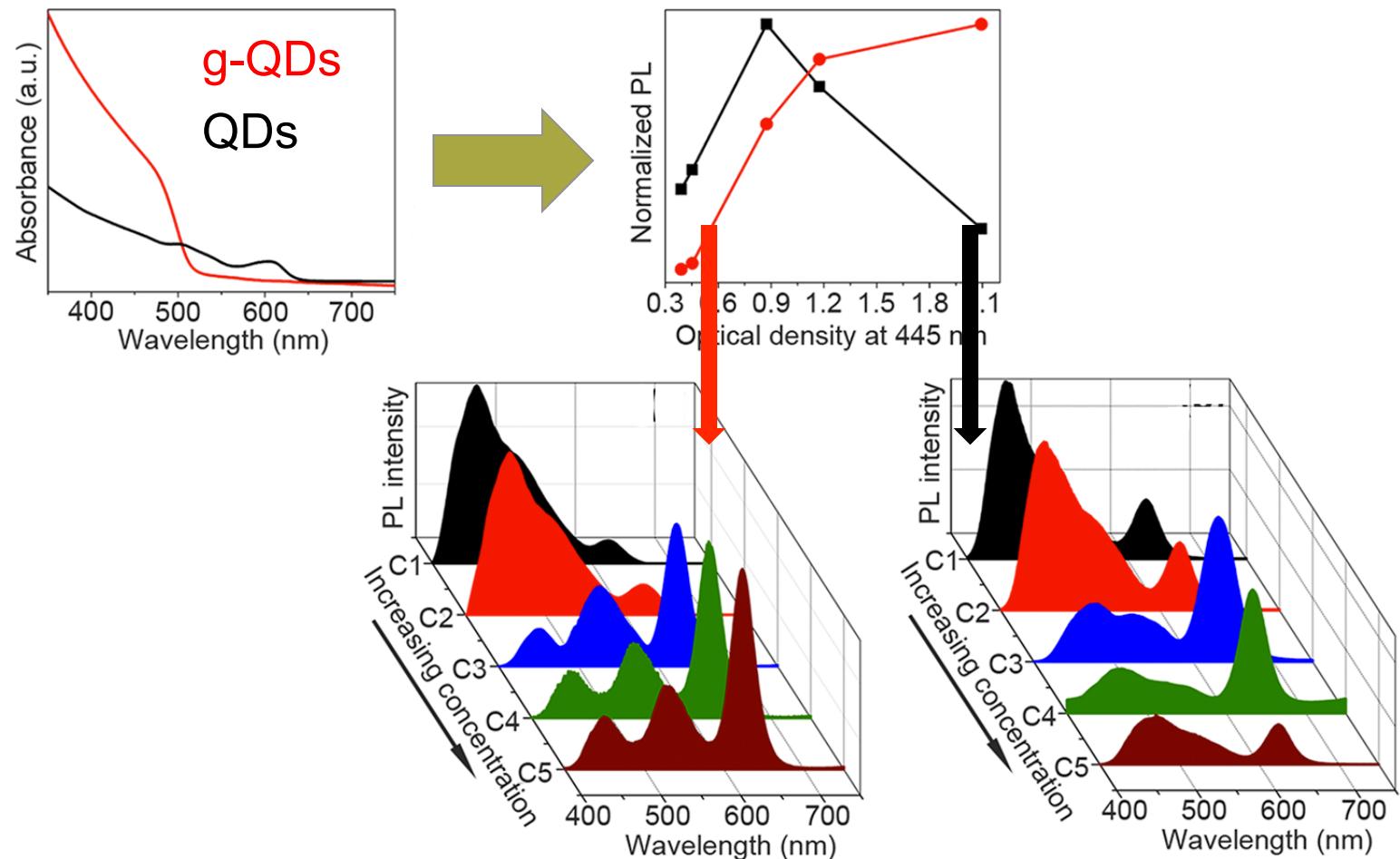
Key g-QD enabling characteristic: *Unique absorption profile*

- Large effective Stokes shift
- Absorption well matched to EL
- High down-conversion efficiency: 22% (green trace)
- High spectral purity: 84%
- ‘Green-yellow’ retained
- 30 Cd/m²



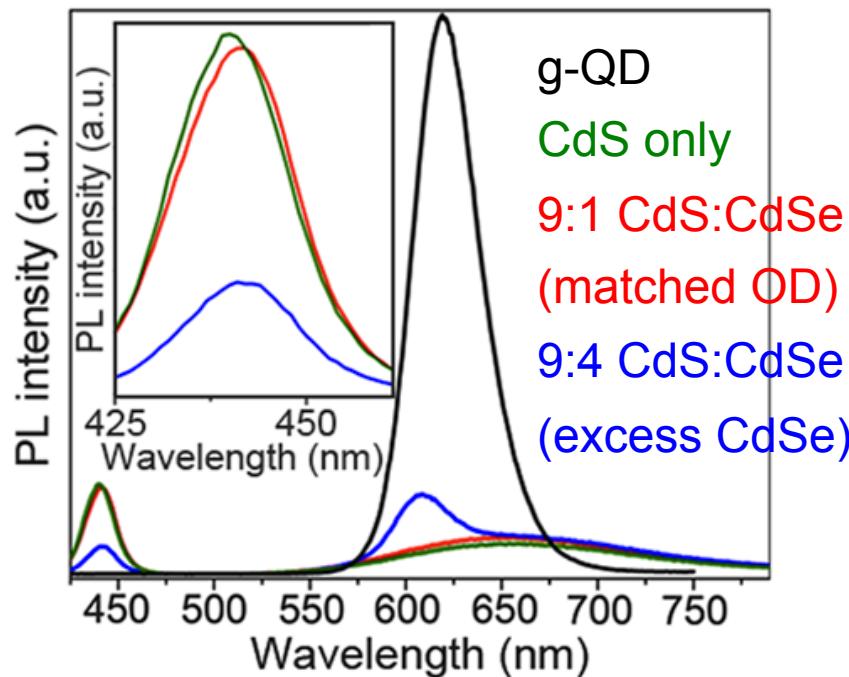
Key g-QD enabling characteristic: *Unique absorption profile*

- g-NQDs can be packed at high densities without self-reabsorption losses



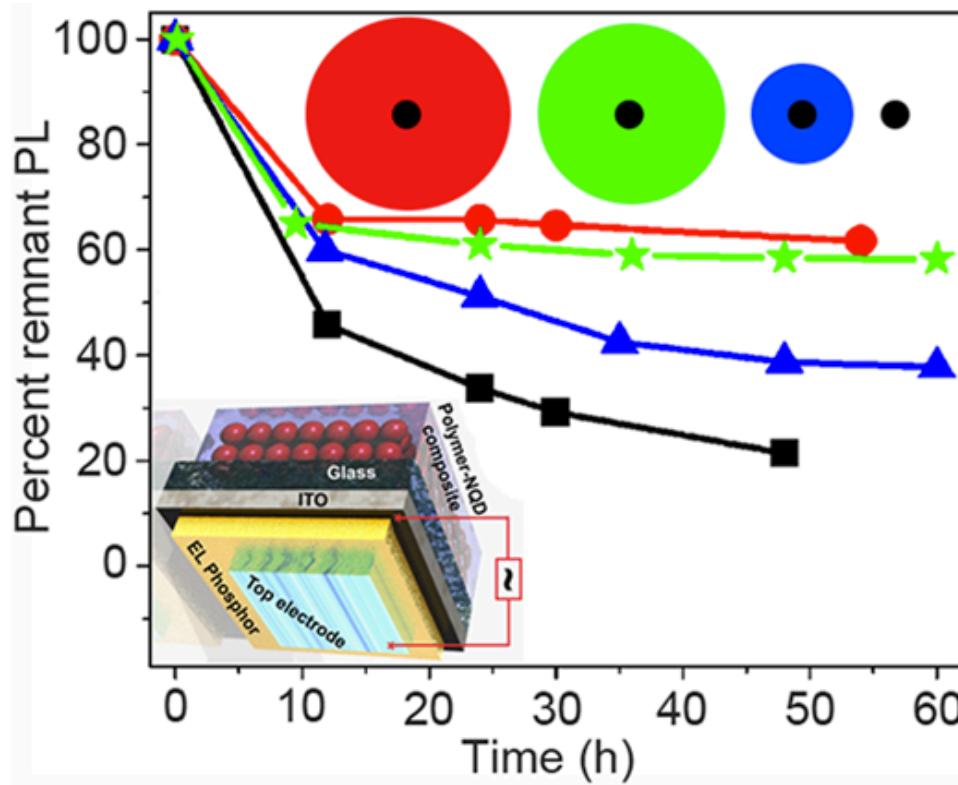
Key g-QD enabling characteristic: *Efficient shell→core energy relaxation*

- In thick-shell QDs, precise engineering of nanoscale architecture affords independent control over absorption & emission properties
- Importantly, these functions remain intimately and efficiently coupled, allowing energy relaxation in g-NQDs to outcompete energy transfer in simple mixtures of absorbers/emitters



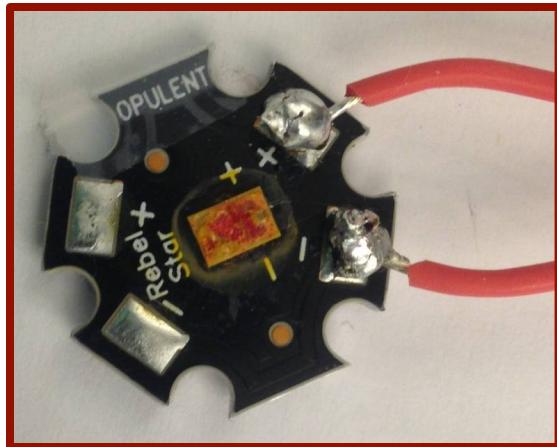
Key g-QD enabling characteristic: *Stability*

- Temporal device stability as a function of continuous biasing time



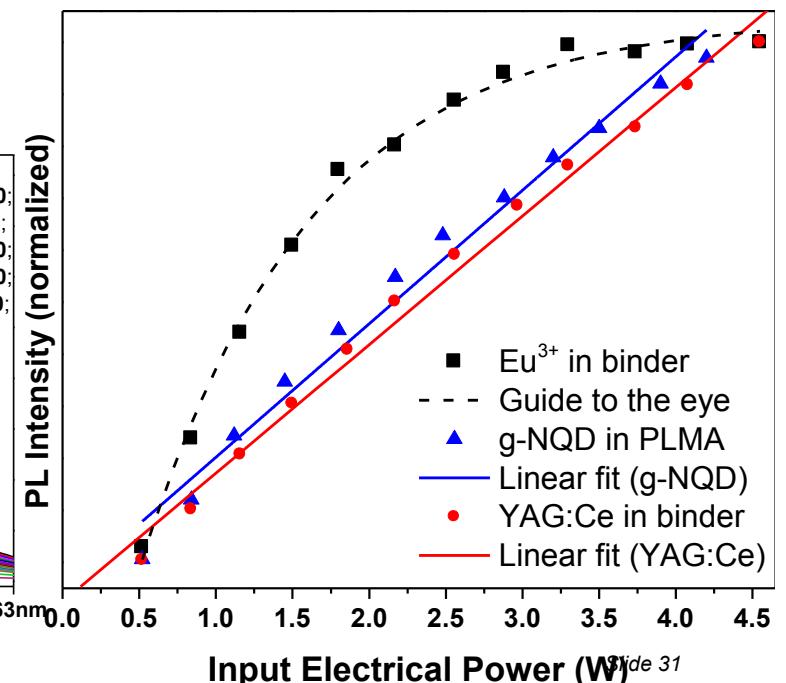
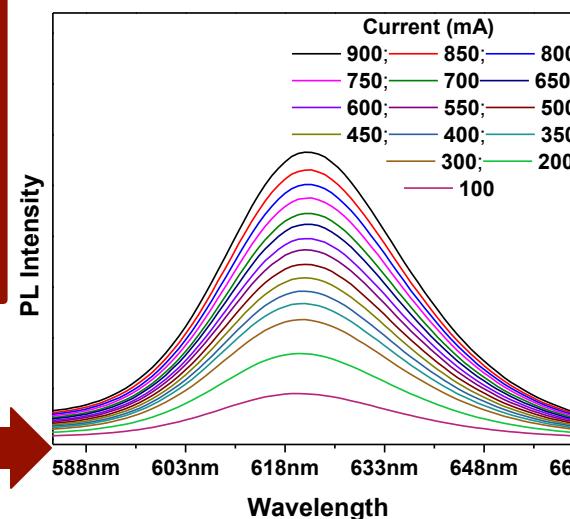
Transitioning proof-of-principle for g-QD down-conversion phosphors to high-power DC LEDs

- Characteristics of LED source: high luminous flux & temperature
 - Many conventional rare-earth phosphors characterized by long radiative lifetimes exhibit PL saturation
 - Many phosphors, including QD alternatives, are reversibly & irreversibly partially quenched by elevated temperature



Transitioning proof-of-principle for g-QD down-conversion phosphors to high-power DC LEDs

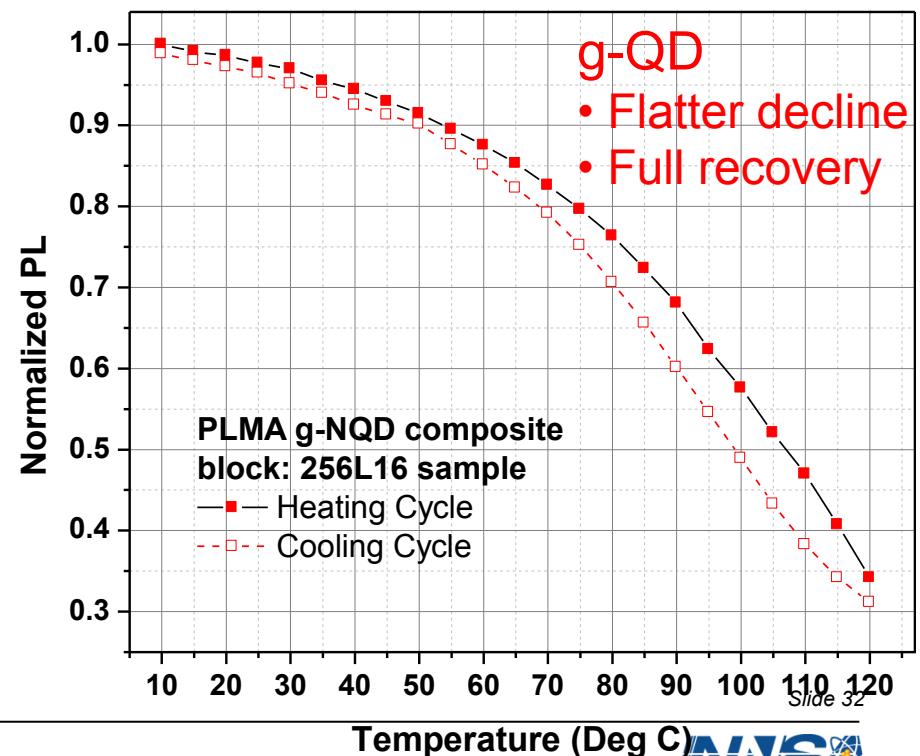
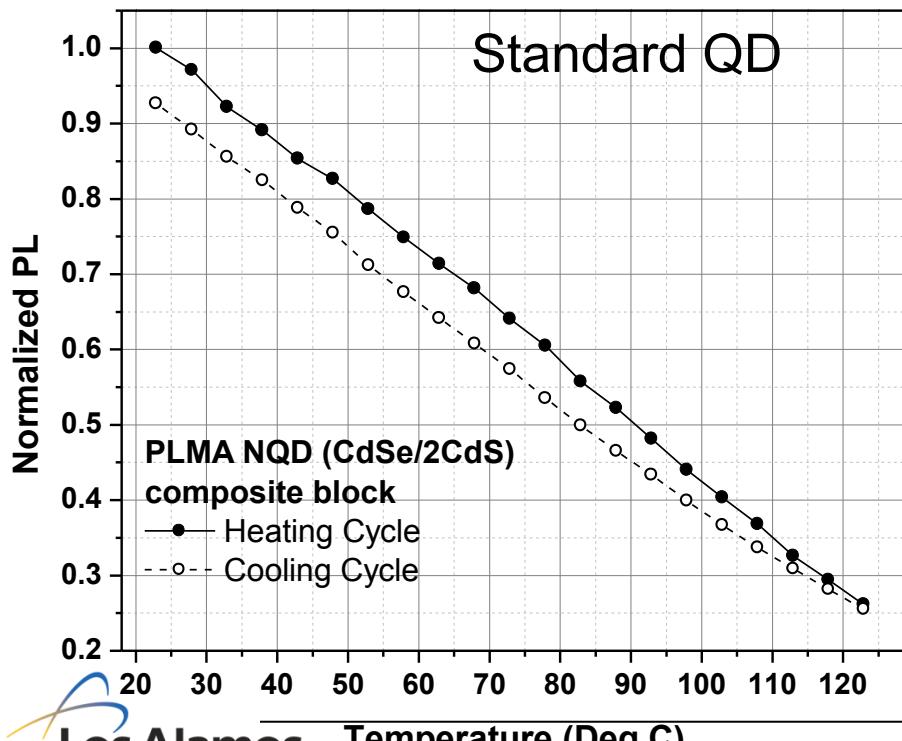
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Slide 31

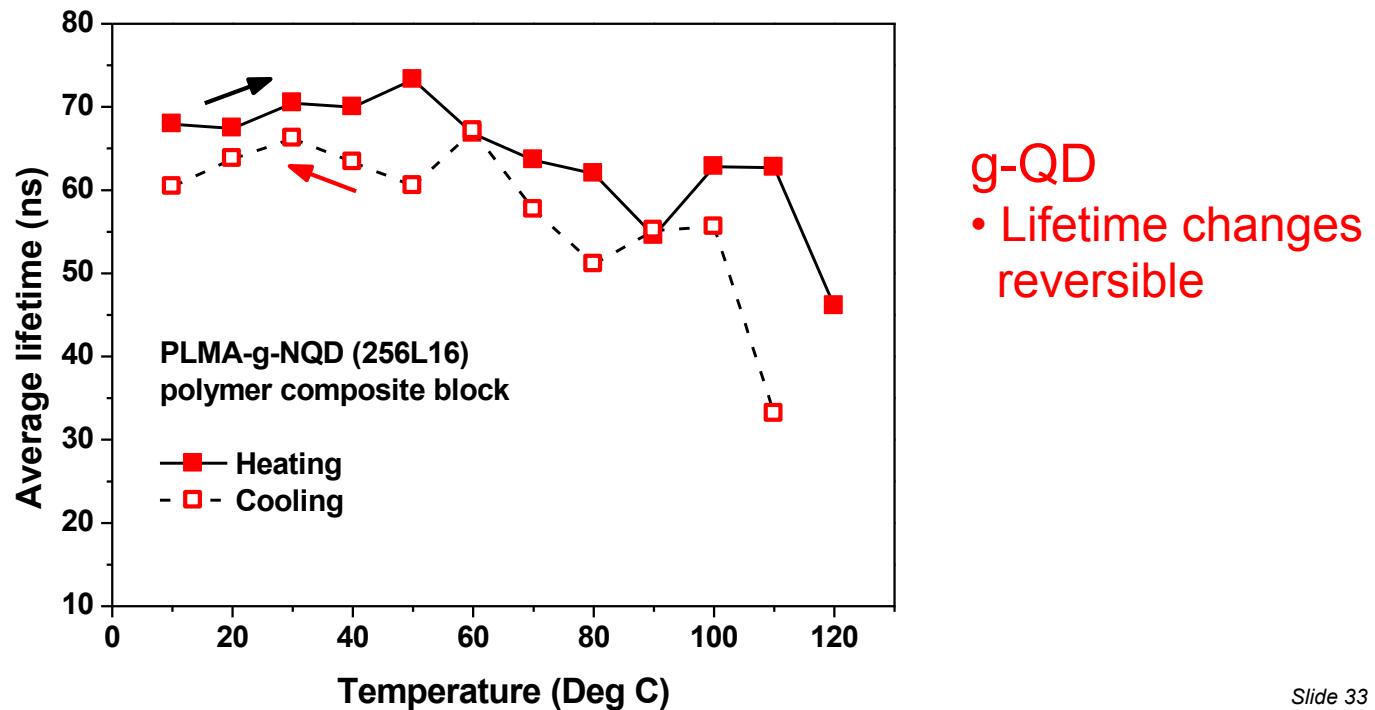
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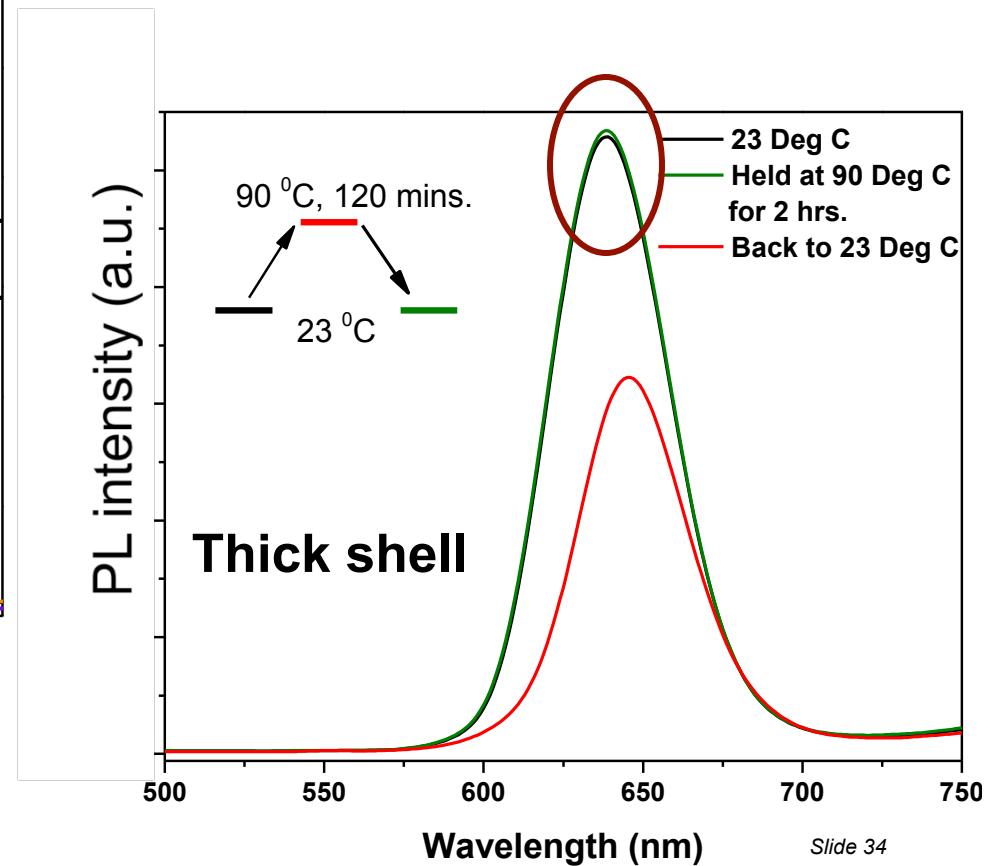
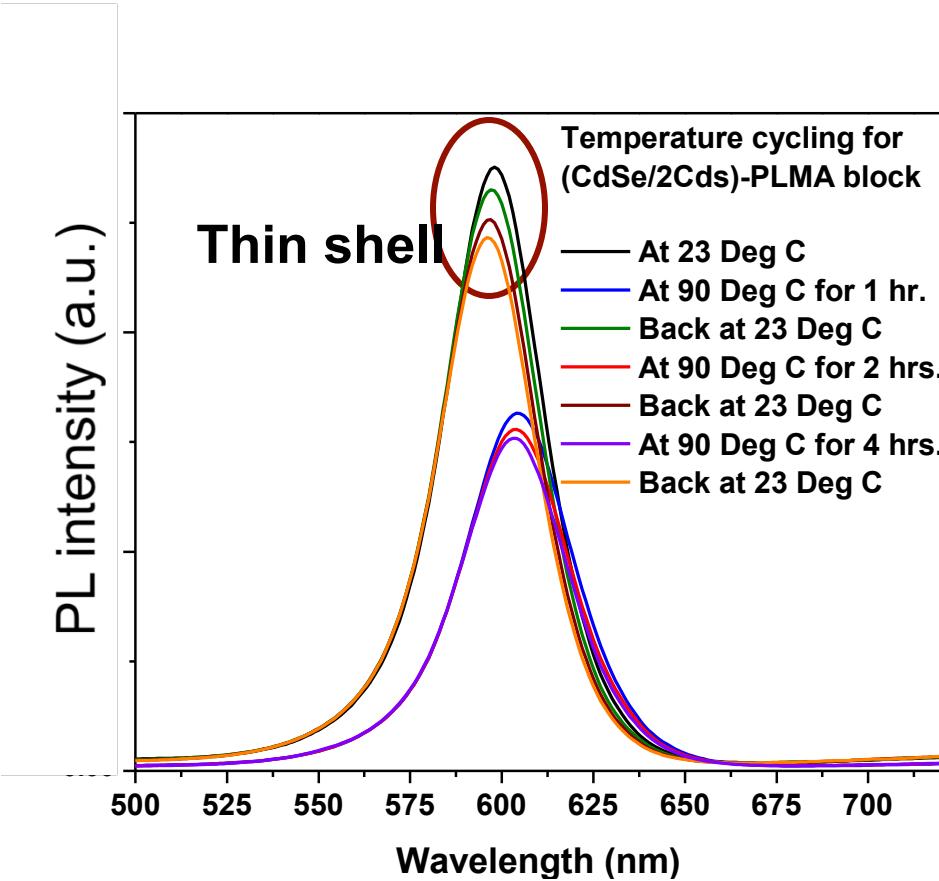


Transitioning proof-of-principle for g-QD down-conversion phosphors to high-power DC LEDs

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Effect of temperature cycling: 23 °C to 90 °C (hold) to 23 °C



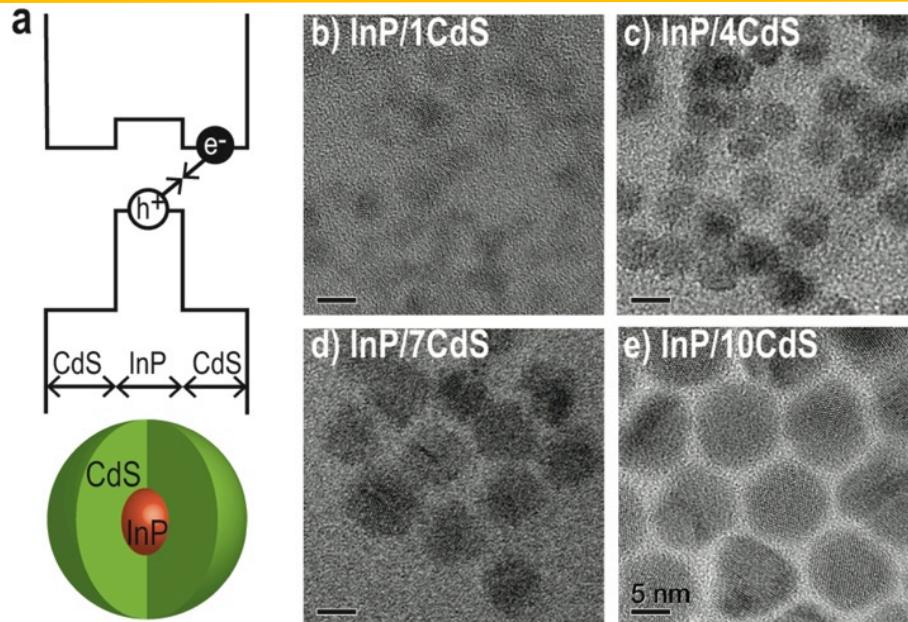
Limited examples of dual suppression of blinking and Auger recombination

- Alloyed CdZnSe/ZnSe system: Wang et al. Nature 2009
 - Suppressed Auger recombination via smoothing of the confinement potential
- Quasi type-II, thick-shell CdSe/CdS: Chen et al. J. Am. Chem. Soc. 2008 and Mahler et al. Nature. Mater. 2008
 - Suppressed ionization/charging via thick, protective shell
 - Suppressed Auger recombination via combined size, carrier-separation and (possibly) interface effects

Moving beyond CdSe:

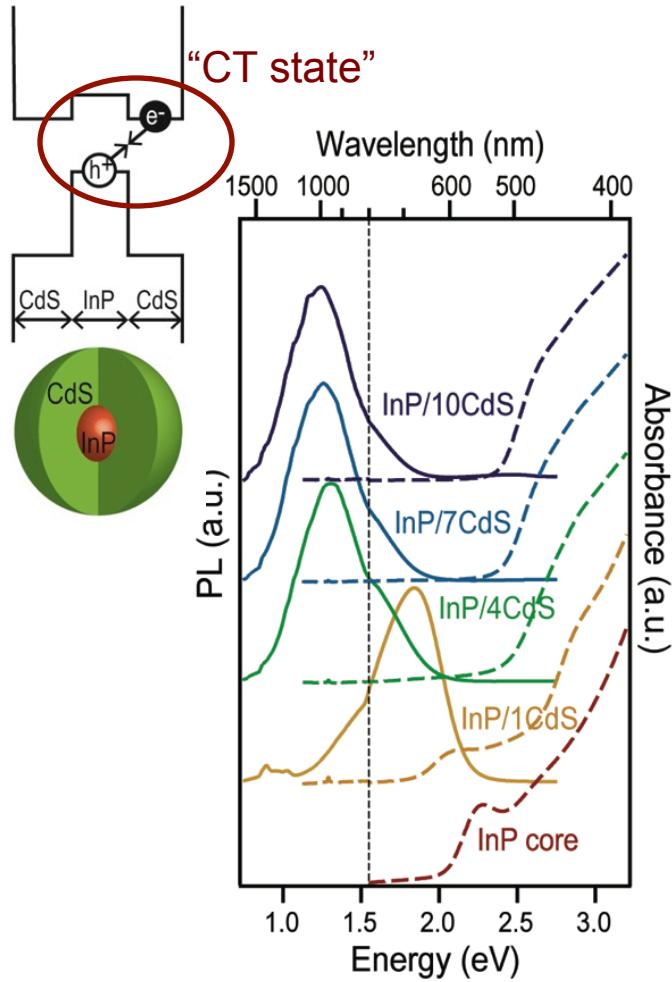
InP-based core/shell heterostructuring also affords suppressed blinking and Auger recombination

InP/CdS g-QDs: Addressing the effects of both electronic structure and shell thickness



- Distinguishing features of the InP/CdS core/shell system
 - Type II electronic structure: Fully charge-separated state
 - Synthetic challenge: InP amenable to high-temperature SILAR growth only after low-T application of first, protective monolayer
 - Susceptibility to surface oxidation
 - Tendency to etch at high-T in presence of acidic/basic ligands
 - Hexagonally faceted, wurtzite shells: Structurally equivalent to CdSe/CdS system

Spectral and dynamic signatures of the type-II heterojunction



- PL red shifts
- Abs broadens/red-shifts then dominated by shell for large “effective Stokes shift”

Unprecedented single-dot infrared-QD blinking studies

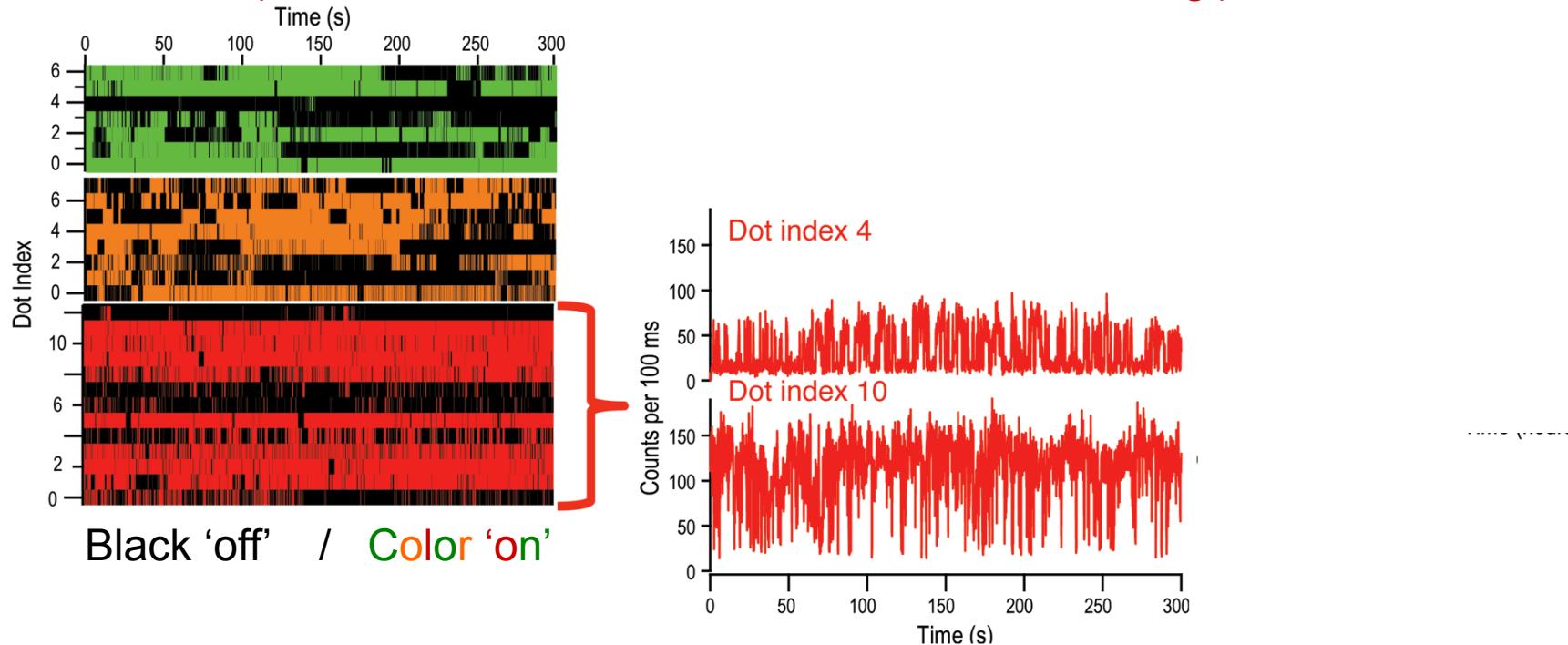
- Room-T blinking studies of type-II QDs previously unknown
 - Though well-known for quasi type-II CdSe/CdS and CdTe/CdTe_xSe_y/CdSe QDs
 - Type II's photobleached
- Single example of single-dot emission from type I infrared emitting QD
 - Correa et al. Nano Lett. 2012 (Bawendi's lab)
 - Specialized superconducting nanowire single-photon detector required to surmount:
 - Materials instability issues
 - ~Long radiative lifetimes
- Our work: Standard sample-preparation and single-photon detection methods adequate

Effect of shell thickness and electronic structure on single-dot blinking behavior and photostability

InP/1CdS (~15-20% dots: on-time % >80%)

InP/4CdS (~15-20% dots: on-time % >80%)

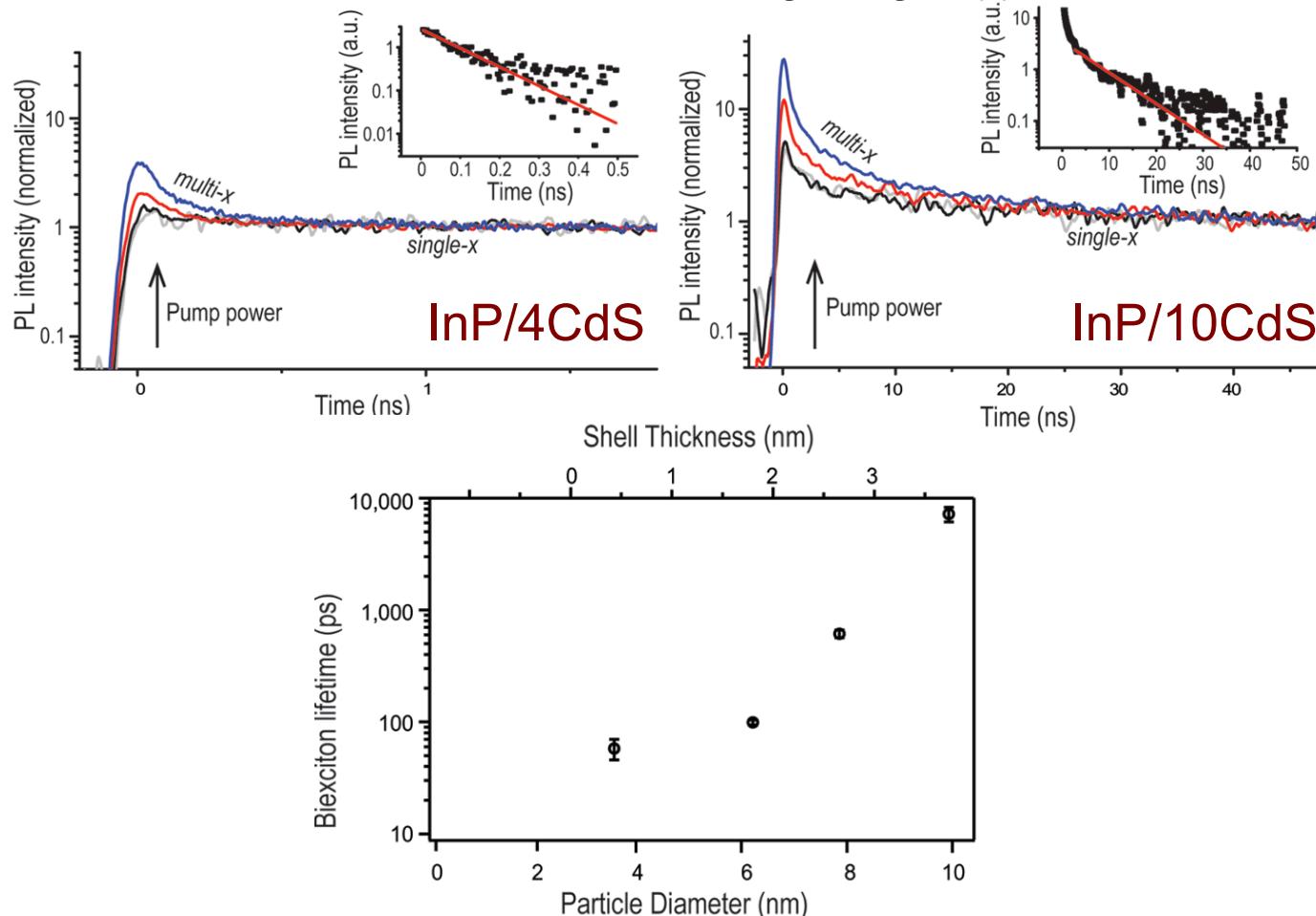
InP/10CdS (>60% dots: on-time % >80%; some 'non-blinking')



- Type-II bandgap alignment transitions the room-T, non-blinking excitonic emission into the near-IR for the first time
- Blinking less clearly shell-thickness dependent; Photobleaching more so

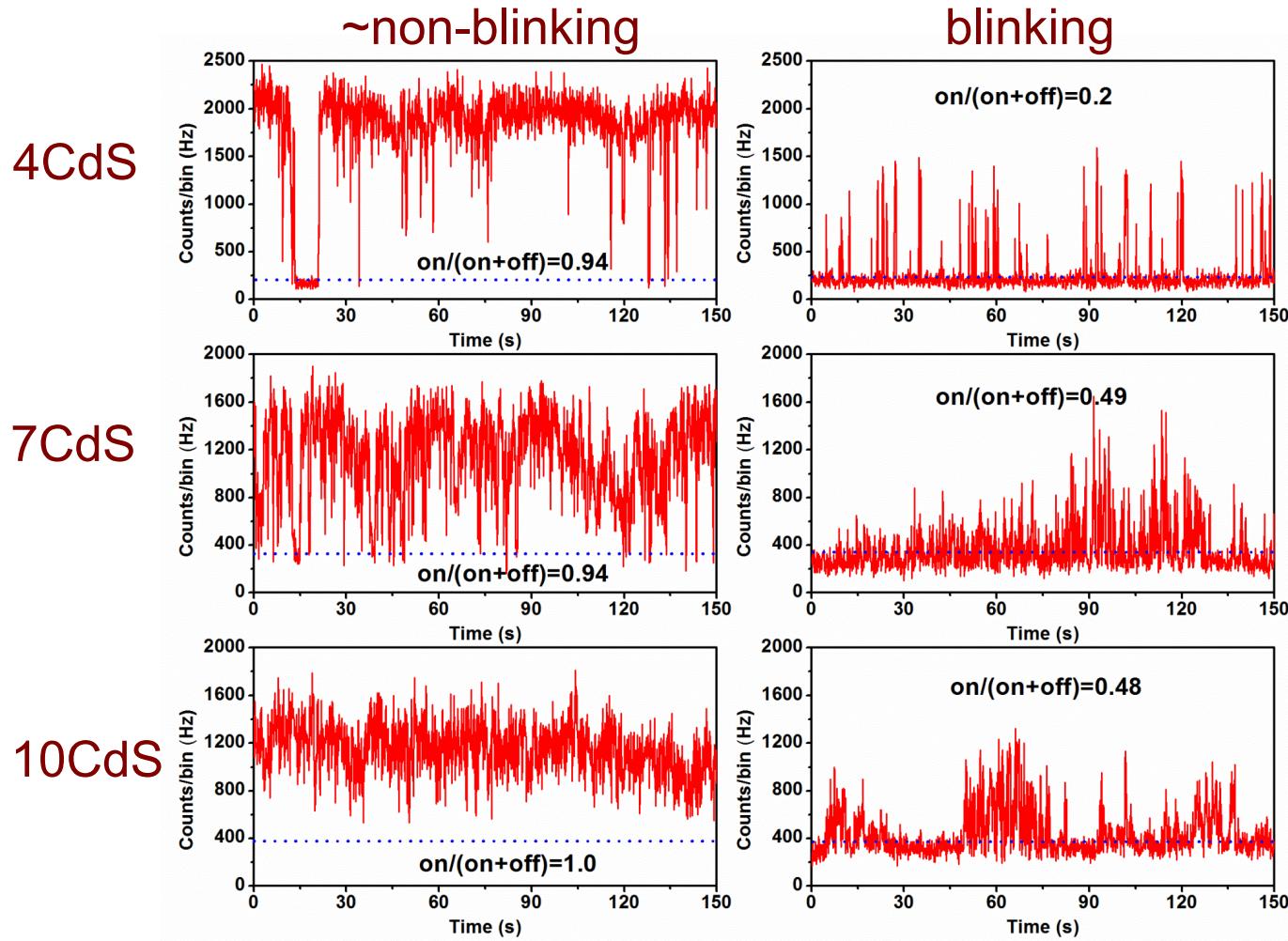
InP/CdS biexciton lifetimes trend with shell thickness

- Pump-intensity-dependent transient photoluminescence: traces converge at long times for thick-shell variants indicating long-lived multiexcitons



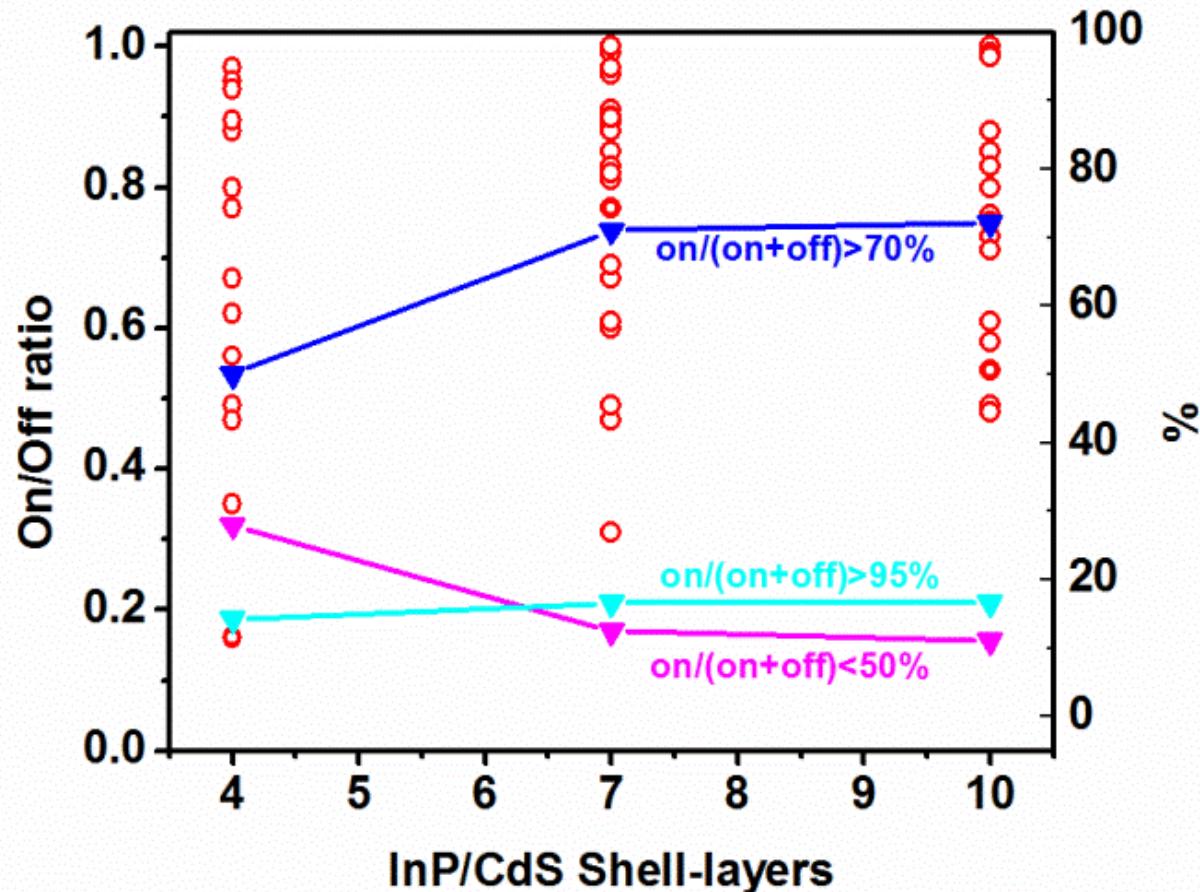
Examples of both non-blinking and blinking behavior for thin and thick-shell InP/CdS

- on/(on+off) ratios defined: “high” and “low” evident at each shell thickness



Detailed blinking statistics reveals nature of shell-thickness dependence in InP/CdS system

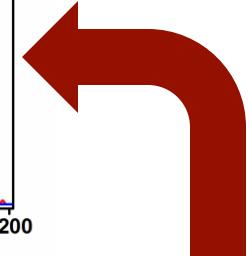
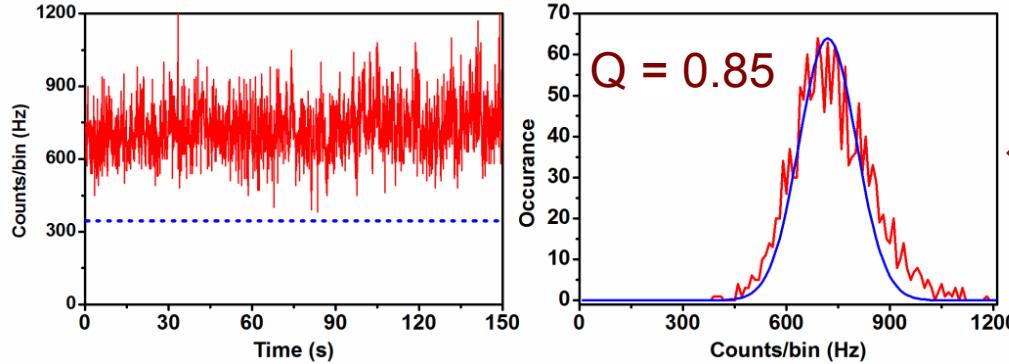
- Non-blinking percentage ~constant, however...
- High on/(on+off) ratios become more prevalent with increasing #CdS
- Low on/(on+off) ratios decline in prevalence



Mandel Q Parameter describes the degree of deviation from a Poissonian distribution of emission intensities

- Case 1: Perfect Poisson distribution

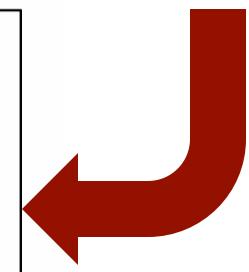
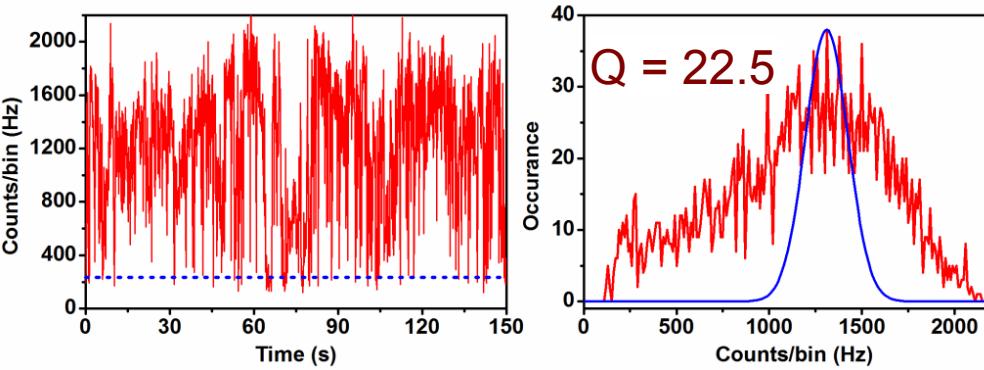
PL intensity trajectory:
 $\text{on}/(\text{on}+\text{off}) > 90\%$



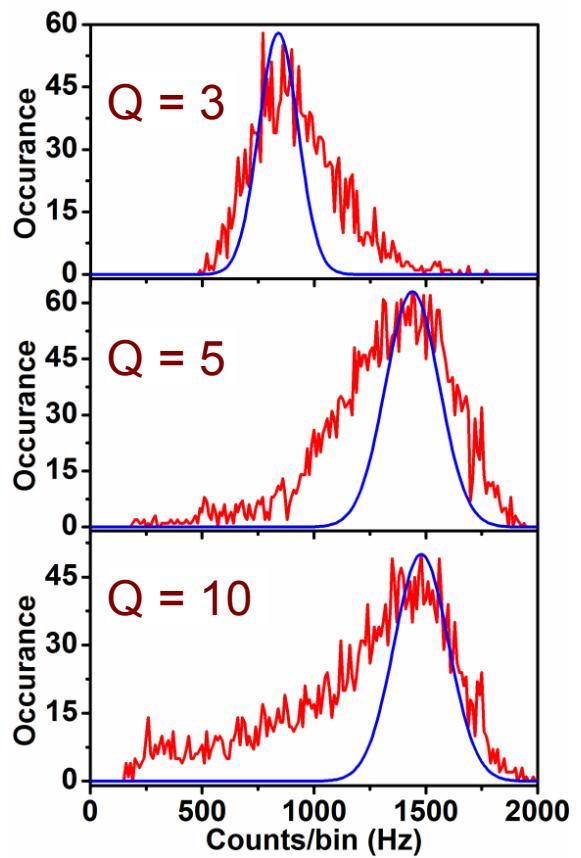
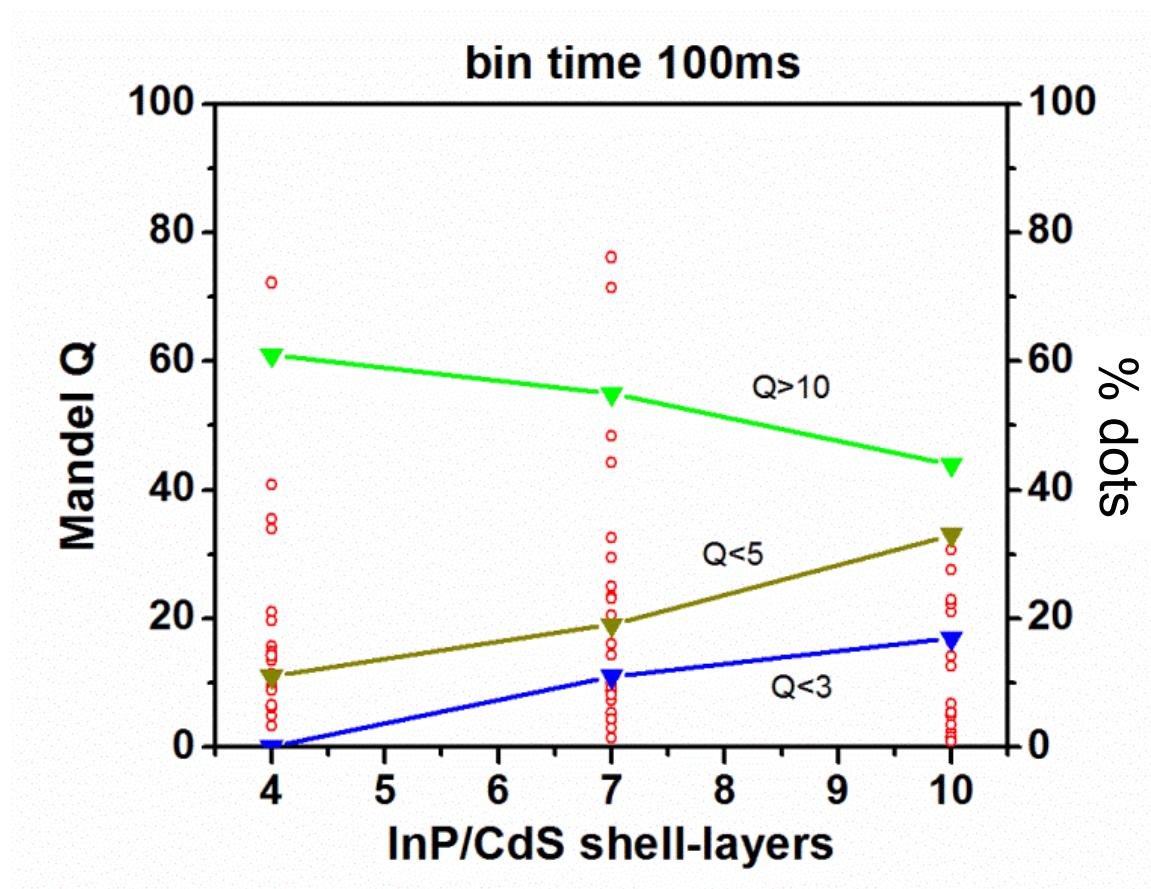
Poissonian fits for
intensity distribution
of the trajectories

- Case 2: Large deviation from Poisson distribution

PL intensity trajectory:
 $\text{on}/(\text{on}+\text{off}) > 90\%$



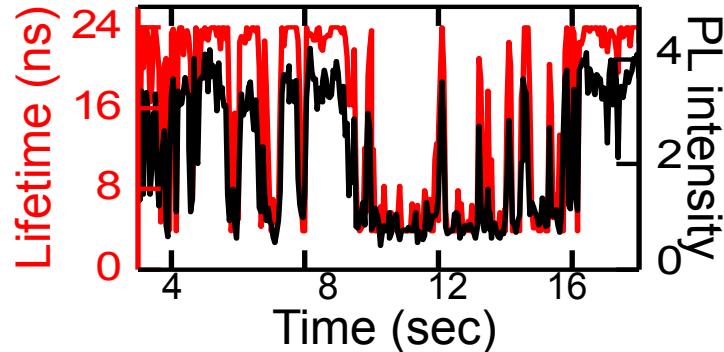
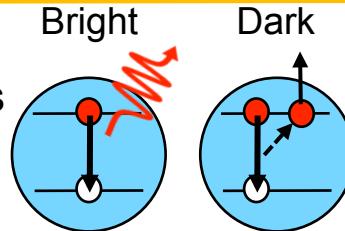
Thicker shells appear to be converging to smaller Q's,
i.e., tighter intensity distributions



New way to think about blinking: Single-dot spectroelectrochemistry reveals two mechanisms

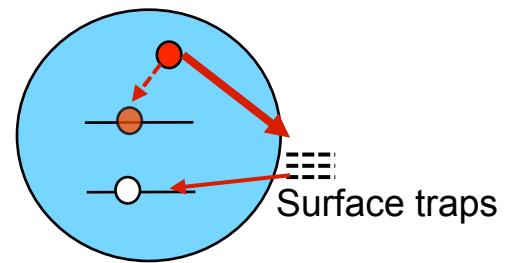
➤ Conventional blinking model: “Type A”

- QDs randomly cycle through uncharged and charged states
- QD blinks ‘off’ due to Auger quenching of charged exciton
- PL intensities and lifetimes fluctuate together



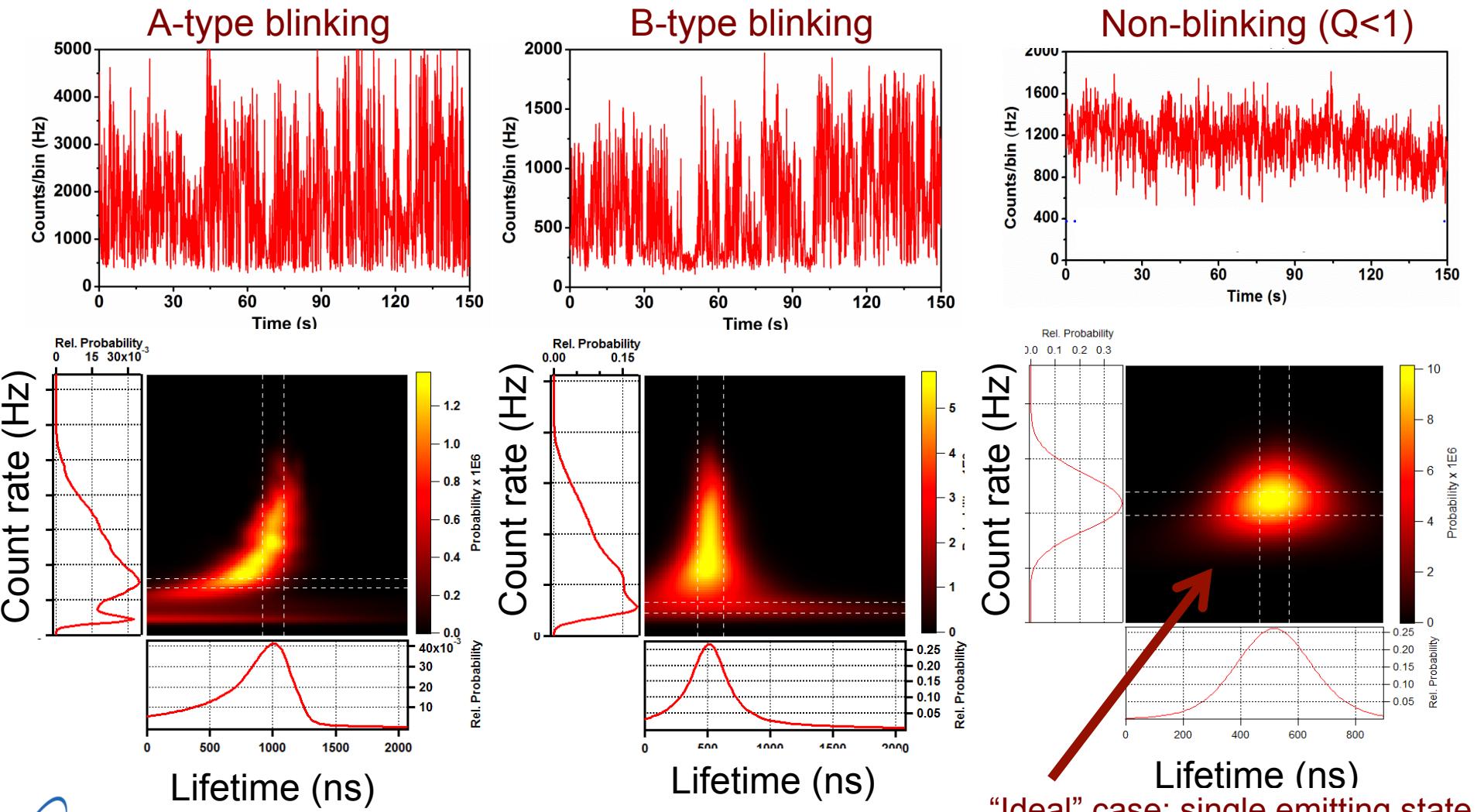
➤ New blinking model: “Type B”

- Trapping of hot electrons to surface states “darkens” PL

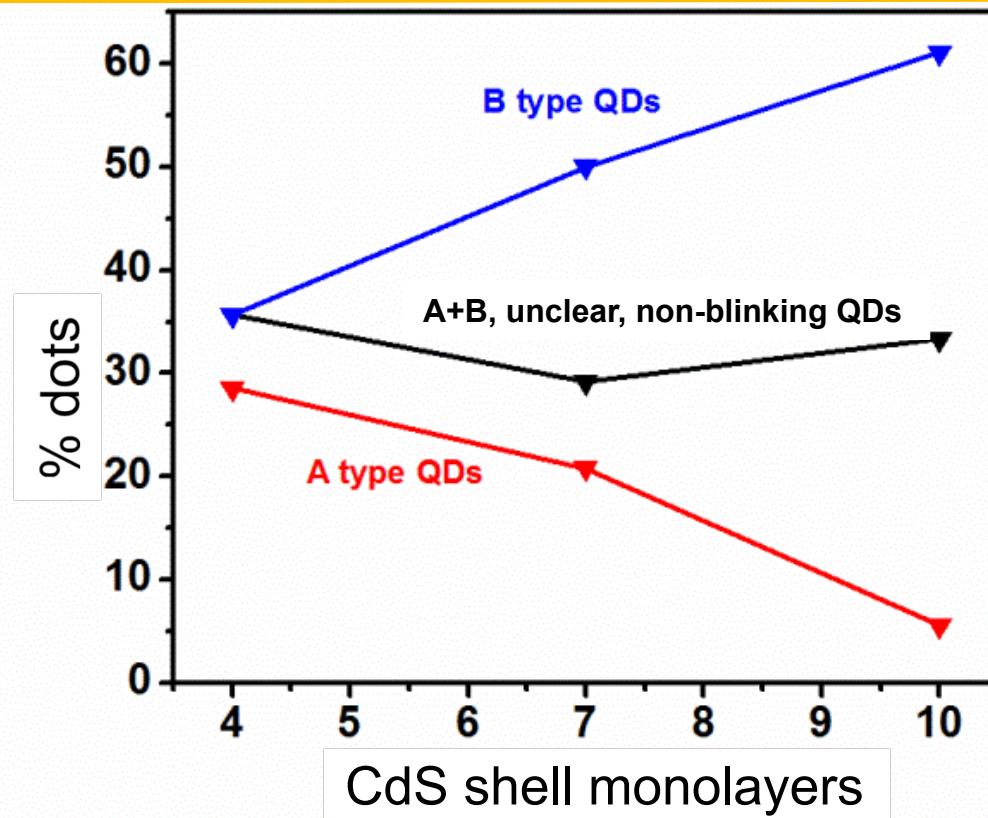


Excitonic emission “short-circuited”

Fluorescence Lifetime Intensity Distributions (FLID): Correlated lifetime-intensity plots reveal more about “blinking” than intensity traces alone



Clear impact of shell thickness on blinking “type” in InP/CdS system

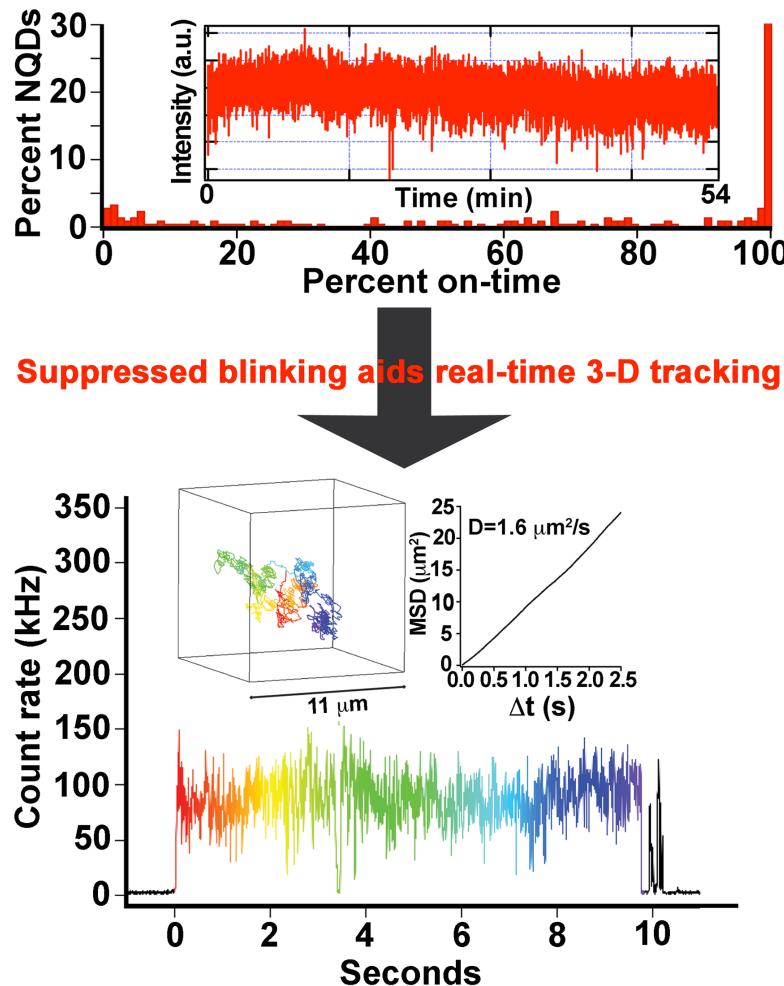


Comment: earlier onset of ‘suppressed blinking’ vs. CdSe/CdS system: *Apparent impact of transition to a fully type-II electronic structure*

- Decline in A-type blinking: consistent with our previous observation that Auger recombination efficiency decreases with increasing shell thickness
- Continued presence of B type blinking: implies even thicker shell is required

Other “light emission” applications of non-blinking g-QDs: 3D particle tracking

- With Jim Werner, R&D 100 Award Winner



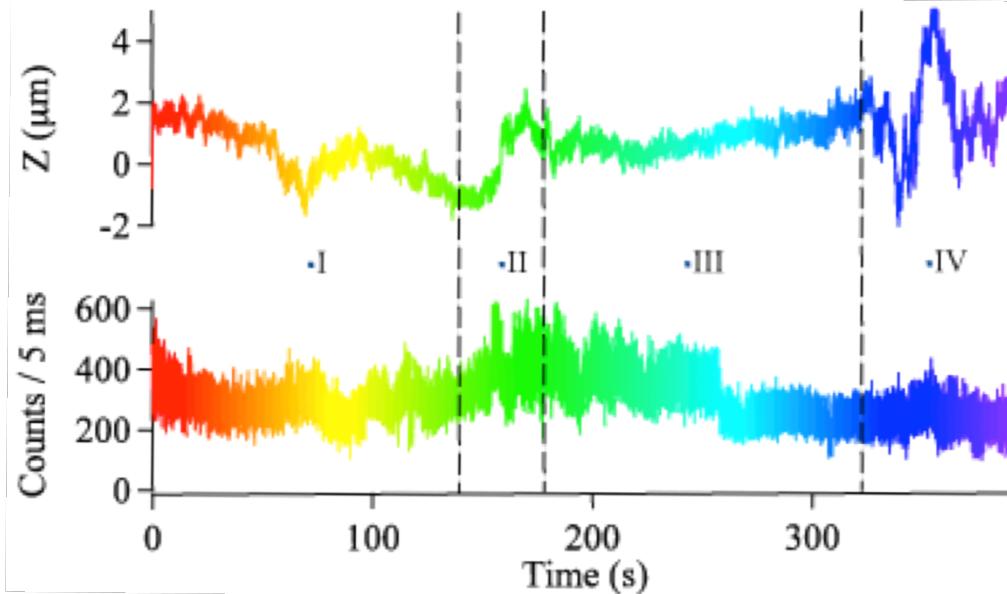
Jim's work more broadly:

- *Three Dimensional Tracking of Individual Quantum Dots*, Lessard, G.A., P.M. Goodwin, and J.H. Werner, *Applied Physics Letters*. 91(22): p. 2224106 /1-3, (2007).
- *Time-Resolved Three-Dimensional Molecular Tracking in Live Cells*, Wells, N.P., G.A. Lessard, P.M. Goodwin, M.E. Phipps, P.J. Cutler, D.S. Lidke, B.S. Wilson, and J.H. Werner, *Nano Letters*. 10(11): p. 4732-4737, (2010).
- *Time-Resolved, Confocal Single Molecule Tracking of Individual Organic Dyes and Fluorescent Proteins in Three Dimensions*, Han, J.J., C. Kiss, A. Bradbury, and J.H. Werner, *ACS Nano*. (2012).

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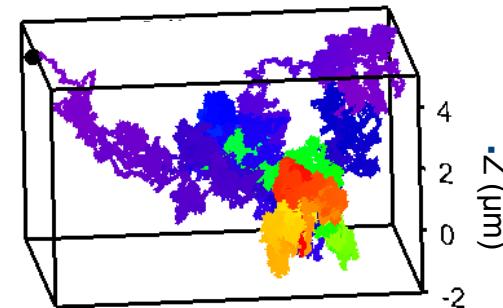
3D single-particle tracking in live mast cells: 20-fold increase in tracking duration!

- Tracked single gQD-IgE for 6.5 min!

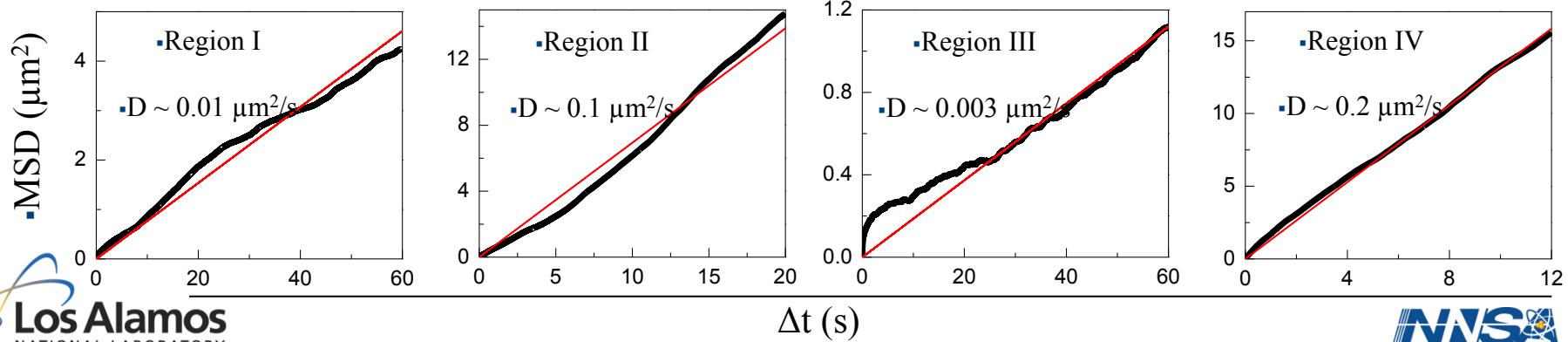


Average tracking duration

- g-QD-IgE = 111 ± 26 s
- Commercial QDot₆₅₅-IgE = 4.8 ± 1.3 s



- Heterogeneity in Diffusion Rates for Single IgE-FcεRI now observable



Conclusions

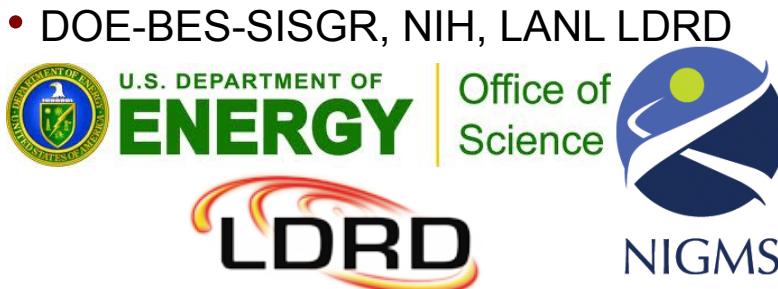
- We addressed the long-standing QD ‘blinking challenge’
- g-QDs nano-structural motif characterized by enabling traits
 - Suppressed Auger recombination
 - Suppressed charging and/or surface trapping
 - Stability independent of surface chemistry/chemical environment
 - Large effective Stokes shift (minimal self, green/yellow re-absorption)
 - Enhanced solid-state performance
 - Etc.
- Demonstrated application of g-QDs in proof-of-concept direct-charge-injection and down-conversion devices
- Extended g-QD ‘approach’ to new InP/CdS system
 - Suppressed blinking, photobleaching and Auger recombination
 - First near-infrared non-blinking QD
- New, ‘sustainable’ compositions are required = ‘non-rare/non-toxic’
 - Simplify synthesis and enhance efficiency for rapid exploration: automation

Acknowledgements

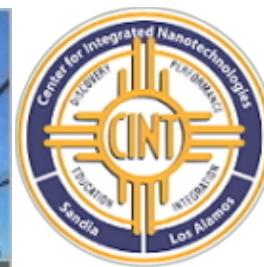
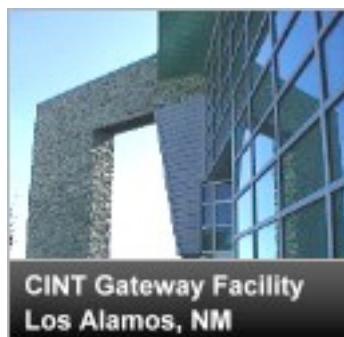
Current LANL CINT g-QD team

- Han Htoon: Staff Scientist, Spectroscopy
- Jim Werner: Staff Scientist, 3D tracking
- Yagnaseni Ghosh: Chem PD
- Allison Dennis: Chem PD
- Janardan Kundu: Device fab/testing PD
- Aaron Keller: 3D particle tracking PD
- Bhola Nath Pal: Device fab/testing PD
- Ben Mangum: Spectroscopy PD

Funding



Janardan Kundu: poster



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(For more information: cint.lanl.gov)